

## 3G rule for attending in person lectures at KIT:

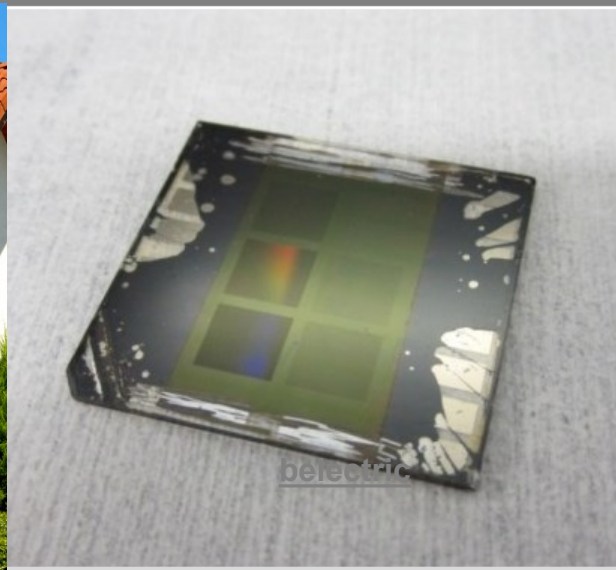
- ***geimpft*** – vaccinated
- ***genesen*** – recovered
- ***getestet*** – tested

## Lecture 15: Light management

**Tenure-Track-Prof. Dr. Ulrich W. Paetzold**

*Institute of Microstructure Technology (IMT), Hermann-von-Helmholtz-Platz 1, 76344 Eggenstein-Leopoldshafen  
Light Technology Institute (LTI), Engesserstrasse 13, Building 30.34, 76131 Karlsruhe*

KIT Focus Optics & Photonics



... nice picture! But ...





**... nice picture! But it should look like this!**



- **Light matters for PV**
  - **Light & solar cell operation principle**
  - Optics losses and their relation to the power conversion efficiency
- State-of-the-art light management in Si solar cells
  - Reducing light reflection
  - Light trapping
  - Avoiding shading and area losses
- Nanophotonic light management concepts
  - Nanophotonic light management in thin film Si solar cells
  - Nanophotonic light management in perovskite solar cells

# What is light?

*“In the beginning God created the heaven and the earth.  
And the earth was without form, and void;  
and darkness was upon the face of the deep.  
And the Spirit of God moved upon the face of the waters.  
And God said, Let there be light: and there was light.”* Genesis, Chapter 1

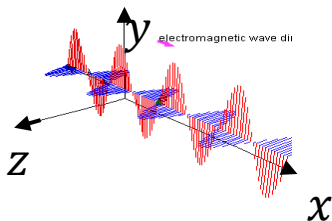
But what God ☺ really said was much more complex:

**Light is a wave**



Maxwell

$$\begin{aligned}\vec{\nabla} \cdot \vec{B} &= 0 & \vec{\nabla} \times \vec{E} &= -\frac{\partial \vec{B}}{\partial t} \\ \vec{\nabla} \cdot \vec{D} &= \rho & \vec{\nabla} \times \vec{H} &= \frac{\partial \vec{D}}{\partial t} + \vec{j}\end{aligned}$$



Wave properties:  
EM radiation has a  
wave like behavior

**... but light is a  
particle**

$$\vec{E} = E_{max} \cos(kx - \omega t) \hat{j}$$

$$\vec{B} = \frac{E_{max}}{c} \cos(kx - \omega t) \hat{k}$$

Photons  
Electrons



Particle properties:  
Light is emitted and absorbed  
as discrete packets of energy,  
i.e. quanta, called photons

# Solar cell: Operating principle

## ■ Solar cell as a diode:

### Principles:

#### Light management

1. The active layer absorbs incident light
2. Charge carriers are created

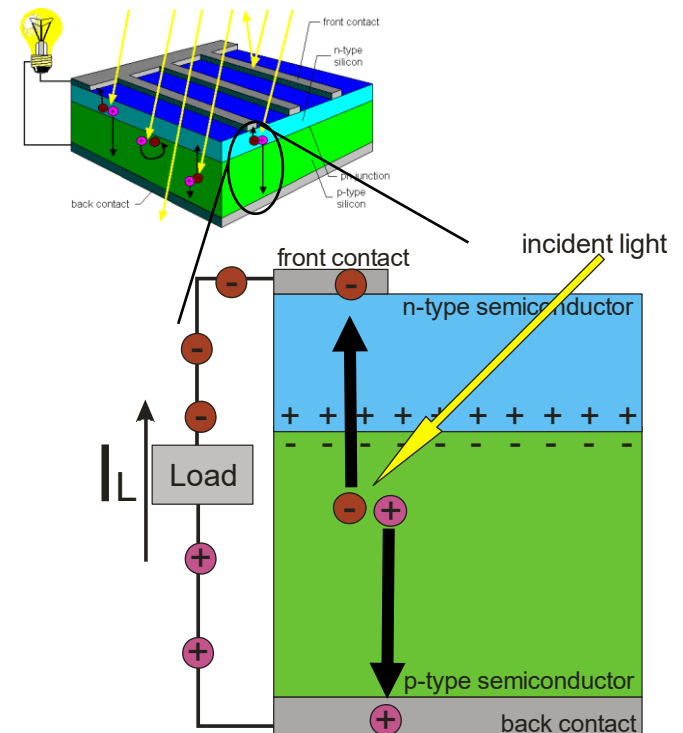
$J_{sc}$

$V_{oc}$

FF

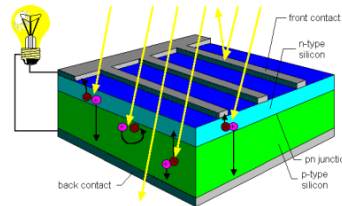
3. The p and n carriers are separated by the structural asymmetry (doping difference)
4. Collection of the separated carriers and the contacts

#### Electron management



# Solar Cell Performance parameters

■  $J_{sc}$ ,  $V_{oc}$  and FF

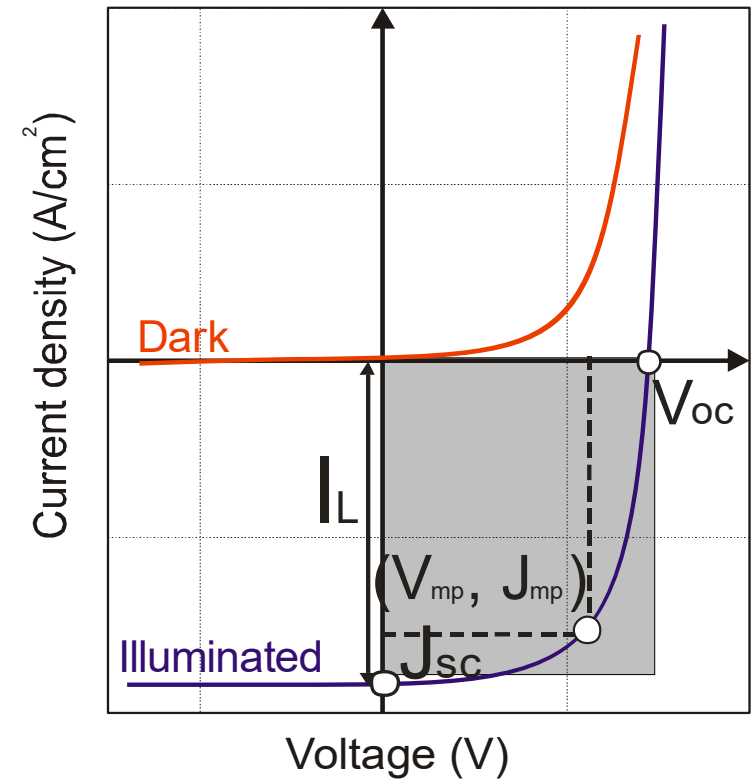


**Fill factor**

$$FF = \frac{V_{mp} \cdot J_{mp}}{V_{oc} \cdot J_{sc}}$$

**Efficiency**

$$\eta = \frac{V_{mp} \cdot J_{mp}}{P_{in}} = \frac{V_{oc} \cdot J_{sc} \cdot FF}{P_{in}}$$



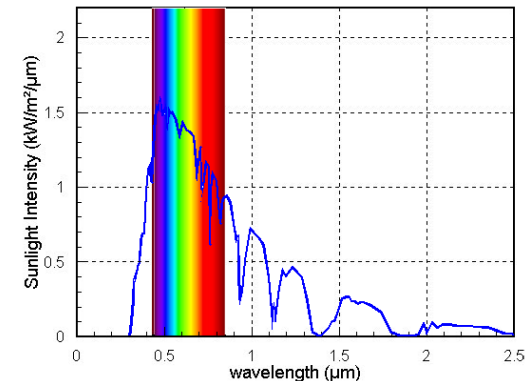


# Solar Cell Performance parameters

## Efficiency

$$\eta = \frac{J_{sc} \cdot V_{oc} \cdot FF}{P_{in}}$$

$$P = q \int_0^{\infty} \frac{hc}{\lambda} \Phi_{ph,\lambda} d\lambda$$



## Open circuit voltage

$$V_{oc} = \frac{k_B T}{q} \cdot \ln \left( \frac{J_{sc}}{J_0} + 1 \right)$$

## Fill factor

$$FF \approx \frac{qV_{oc} / k_B T - \ln(0.72 + qV_{oc} / k_B T)}{1 + qV_{oc} / k_B T}$$

## Short circuit current density

$$J_{sc} = q \int_0^{\infty} EQE(\lambda) \Phi_{ph,\lambda} d\lambda$$

$$J_{sc} = q \int_0^{E_G} A(\lambda) \Phi_{ph,\lambda} d\lambda \times$$

optics of the solar cell

Which parameter relates most to optics ?

Relates directly to optics/light

Relates indirectly to optics/light

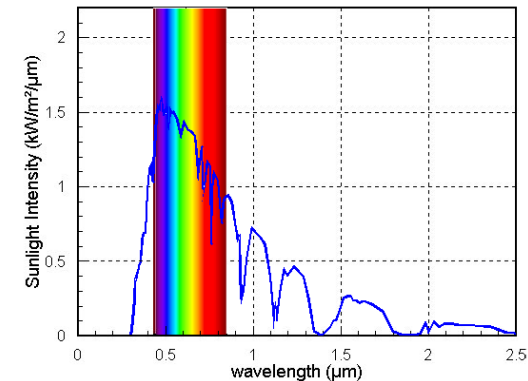
# Solar Cell Performance parameters

## Efficiency

$$\eta = \frac{J_{sc} \cdot V_{oc} \cdot FF}{P_{in}}$$

## Irradiated intensity

$$P_{in} = \int_0^{\infty} P(\lambda) d\lambda$$



## Open circuit voltage

$$V_{oc} = \frac{k_B T}{q} \cdot \ln \left( \frac{J_{sc}}{J_0} + 1 \right)$$

## Fill factor

$$FF \approx \frac{qV_{oc} / k_B T - \ln(0.72 + qV_{oc} / k_B T)}{1 + qV_{oc} / k_B T}$$

## Short circuit current density

$$J_{sc} = -q \int_0^{\infty} EQE(\lambda) \Phi_{ph,\lambda} d\lambda$$

$$J_{sc} = -q \int_0^{E_G} \Phi_{ph,\lambda} d\lambda \times IQE_{opt} \times IQE_{el} \times (1 - R) \times \frac{A_f}{A_{tot}}$$

See also textbook p. 136.

# Solar Cell Efficiency

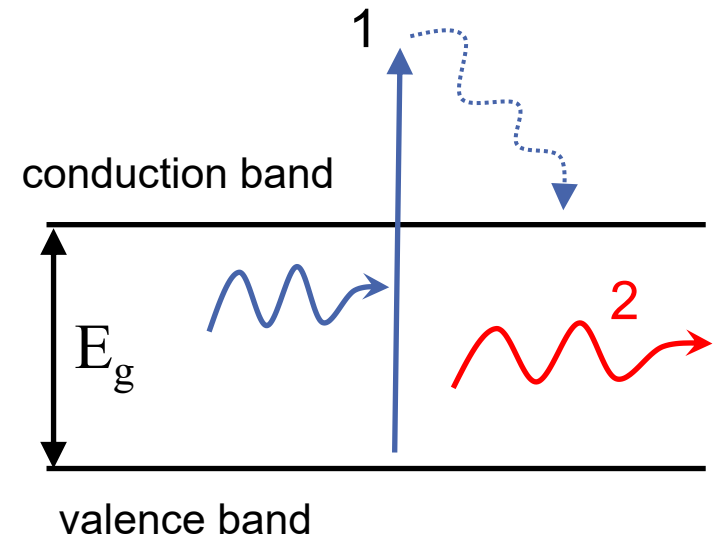
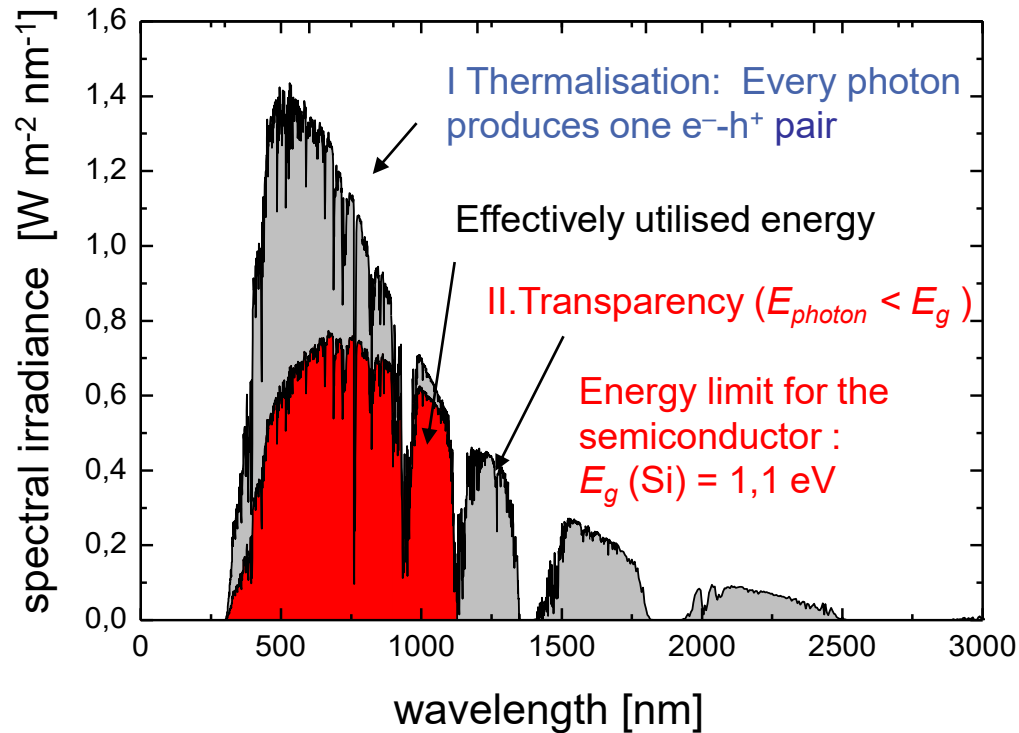
If we discriminate the optical aspects in the device we get:

$$\eta = \underbrace{\frac{\int_0^{E_G} \frac{hc}{\lambda} \Phi_{ph,\lambda} d\lambda}{\int_0^{\infty} \frac{hc}{\lambda} \Phi_{ph,\lambda} d\lambda}}_{\text{Photons}} \times \underbrace{\frac{E_G \int_0^{E_G} \Phi_{ph,\lambda} d\lambda}{\int_0^{E_G} \frac{hc}{\lambda} \Phi_{ph,\lambda} d\lambda}}_{\text{Photons}} \times \underbrace{IQE_{el}}_{\text{Charge carrier dynamics}} \times \underbrace{(1 - R)}_{\text{Photons}} \times \underbrace{\frac{A_f}{A_{tot}}}_{\text{Photons}} \times \underbrace{IQE_{opt}}_{\text{Photons}} \times \underbrace{\frac{eV_{oc}}{E_G}}_{\text{Charge carrier dynamics}} \times \underbrace{FF}_{\text{Charge carrier dynamics}}$$

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# Solar Cell Efficiency



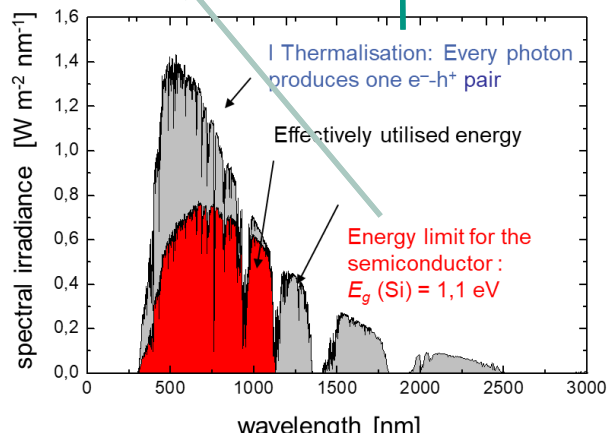
# Solar Cell Efficiency

If we discriminate the optical aspects in the device we get:

Photons

Charge carrier  
dynamics

$$\eta = \frac{\int_0^{E_G} \frac{hc}{\lambda} \Phi_{ph,\lambda} d\lambda}{\int_0^{\infty} \frac{hc}{\lambda} \Phi_{ph,\lambda} d\lambda} \times \frac{E_G \int_0^{E_G} \Phi_{ph,\lambda} d\lambda}{\int_0^{E_G} \frac{hc}{\lambda} \Phi_{ph,\lambda} d\lambda} \times IQE_{el} \times (1 - R) \times \frac{A_f}{A_{tot}} \times IQE_{opt} \times \frac{eV_{OC}}{E_G} \times FF$$



**Thermalization  
loss**

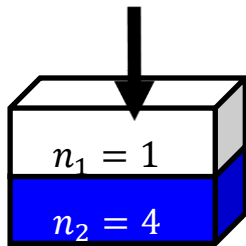
**Sub band gap  
abs. loss**

# Reflectance at the surface

## air/Si interface

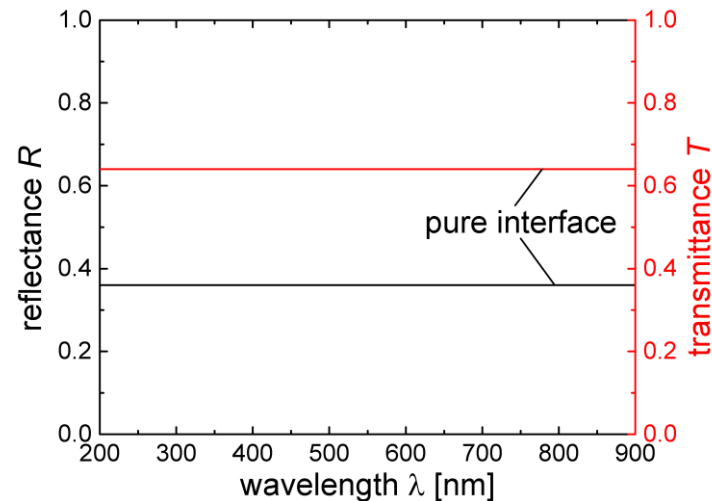
$$n_{\text{air}} = 1$$

$$n_{\text{Si}} = 4$$



$$R = \left( \frac{n_{\text{top}} - n_{\text{bot}}}{n_{\text{top}} + n_{\text{bot}}} \right)^2$$

$$T = \frac{4n_{\text{top}}n_{\text{bot}}}{(n_{\text{top}} + n_{\text{bot}})^2}$$



## Strategies to overcome:

1. Anti reflection coatings
2. Microtextures which enforce multiple incidences on the surface
3. Nanotextures which induce a gradual matching of the refractive index.

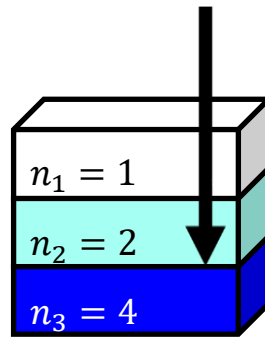
# Reflectance at the surface

## single layer ARC

$$n_{\text{air}} = 1, n_{\text{Si}} = 4$$

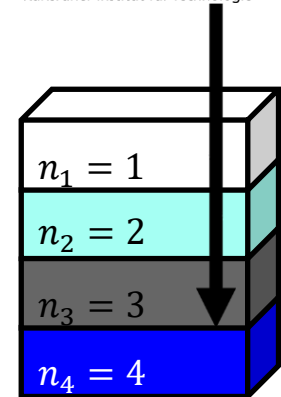
$$n_{\text{ARC}} = 2$$

$$n_{\text{ARC}} = \sqrt{n_{\text{top}} \times n_{\text{bot}}}$$

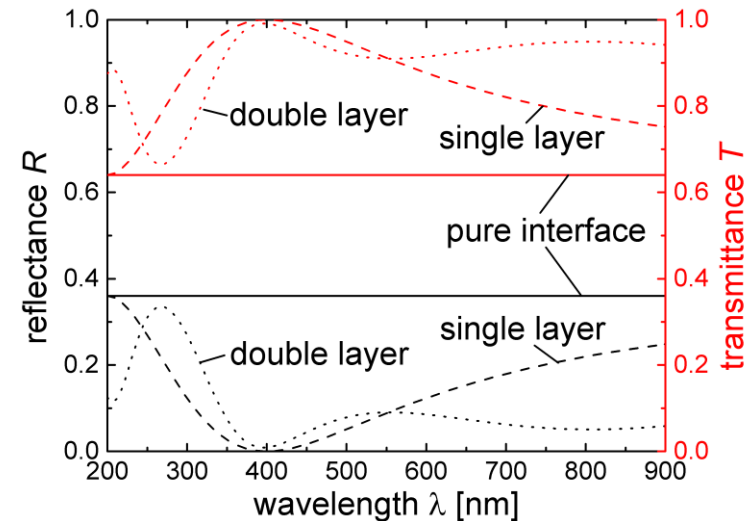
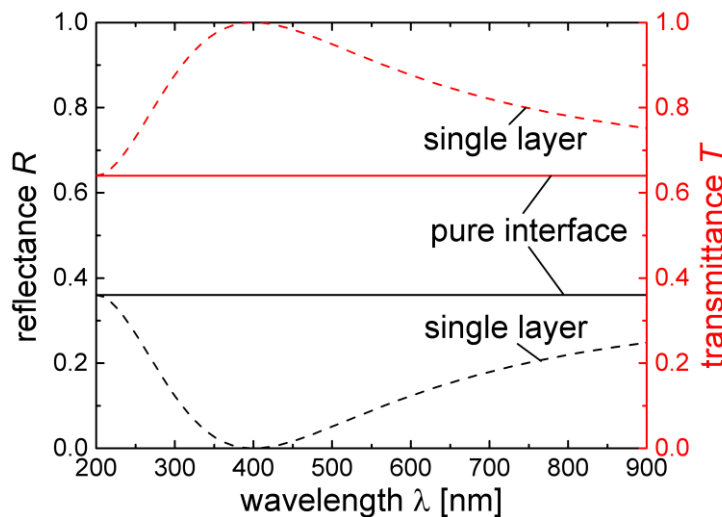


## multi-layer ARC

- further improvement



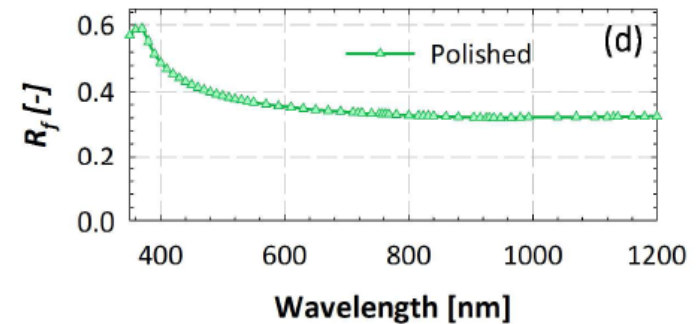
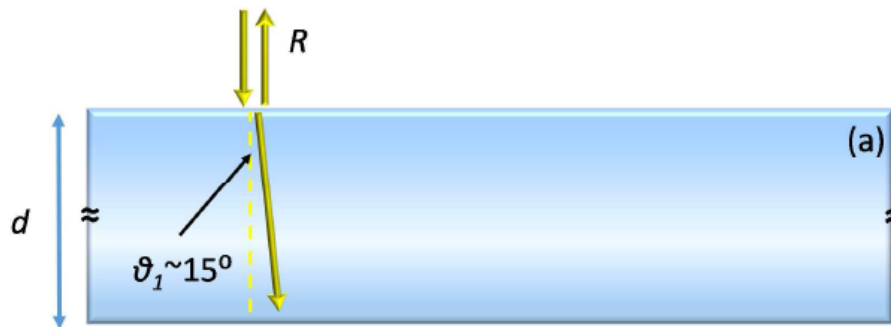
## + interference effects!



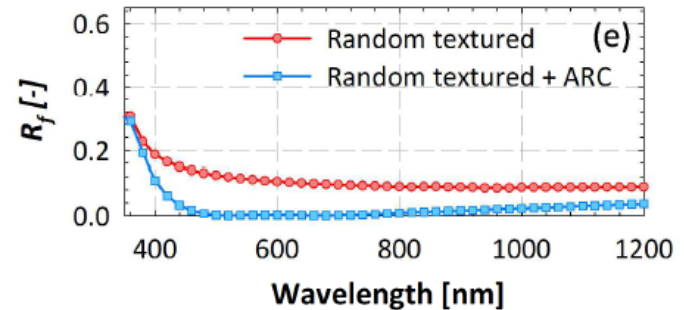
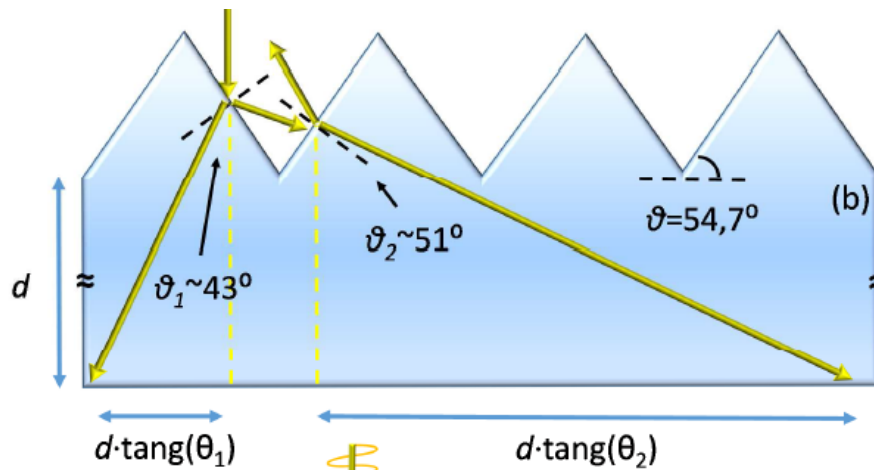


# Reflectance at the surface

## Textured interfaces reduce reflectance by multiple incidences

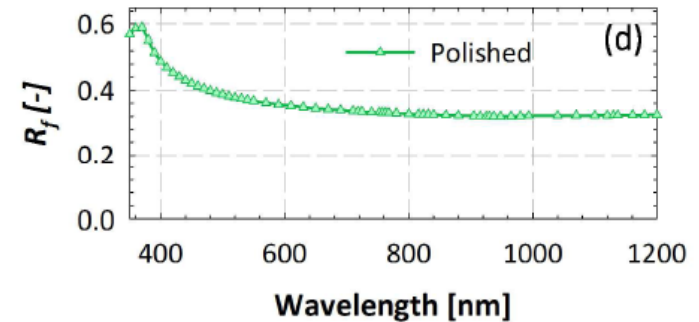


dimension of texture  $\gg$  wavelength of light

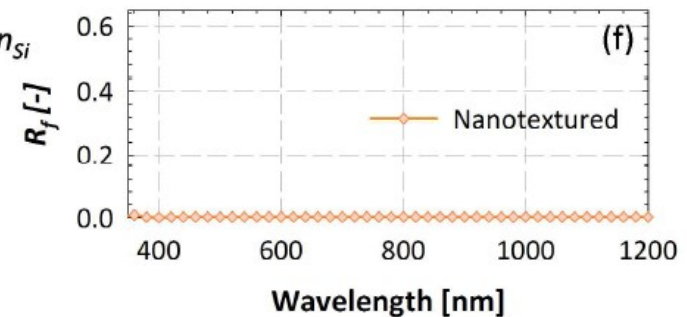
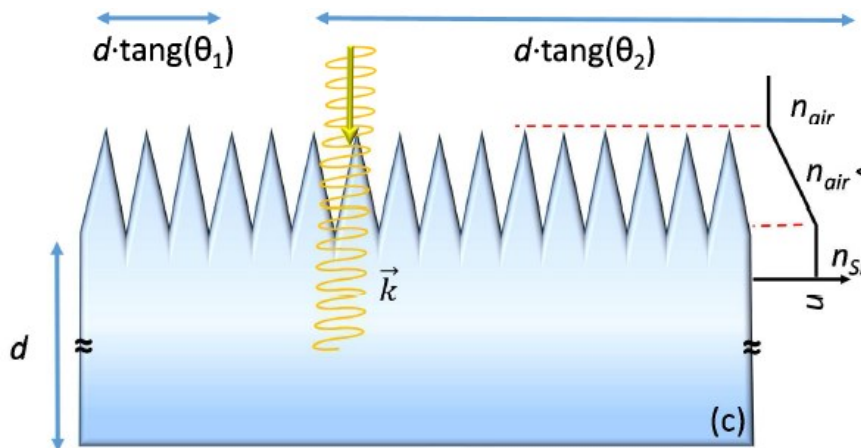


# Reflectance at the surface

Nanoscale textures can reduce reflectance by “effective medium ARC”



dimension of texture  $\ll$  wavelength of light



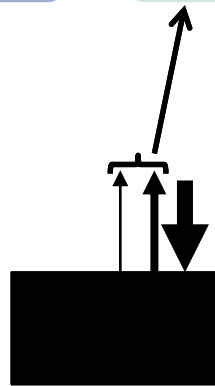
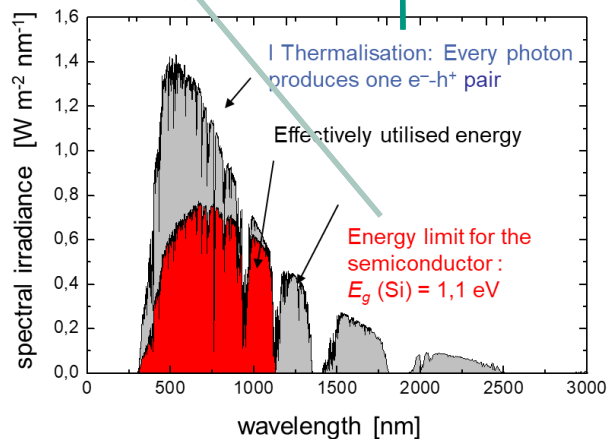
# Solar Cell Efficiency

If we discriminate the optical aspects in the device we get:

Photons

Charge carrier  
dynamics

$$\eta = \frac{\int_0^{E_G} \frac{hc}{\lambda} \Phi_{ph,\lambda} d\lambda}{\int_0^{\infty} \frac{hc}{\lambda} \Phi_{ph,\lambda} d\lambda} \times \frac{E_G \int_0^{E_G} \Phi_{ph,\lambda} d\lambda}{\int_0^{E_G} \frac{hc}{\lambda} \Phi_{ph,\lambda} d\lambda} \times IQE_{el} \times (1 - R) \times \frac{A_f}{A_{tot}} \times IQE_{opt} \times \frac{eV_{OC}}{E_G} \times FF$$



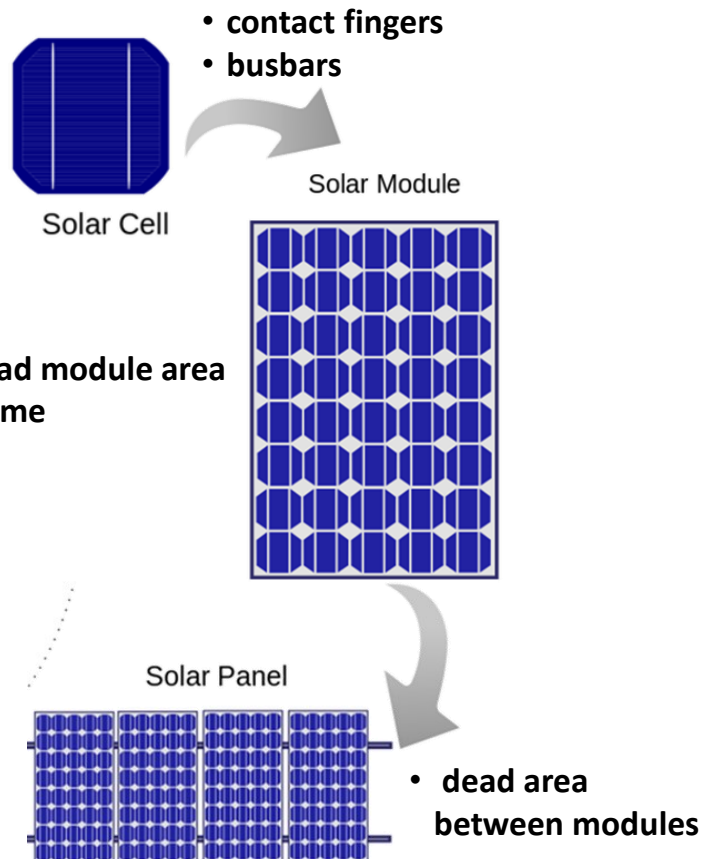
Thermalization  
loss

Sub band gap  
abs. loss

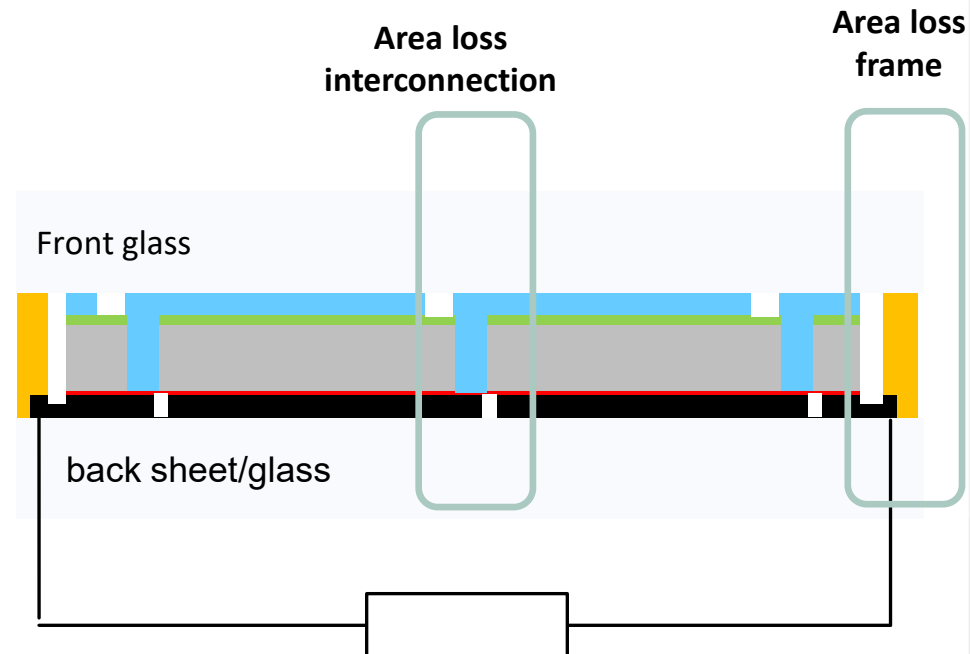
Reflection

# Losses of active area

## Silicon solar cell technology



## Thin-film solar cell technologies





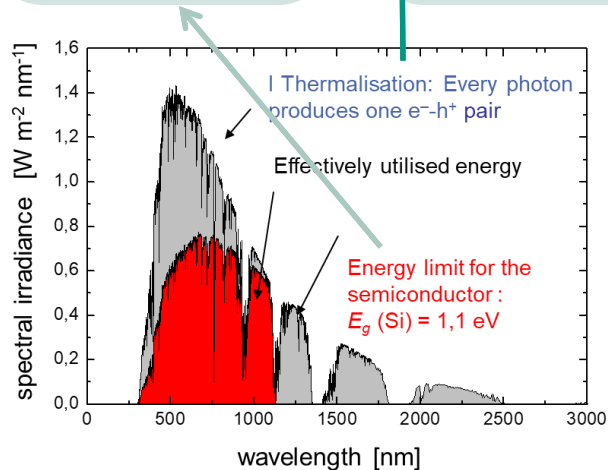
# Solar Cell Efficiency

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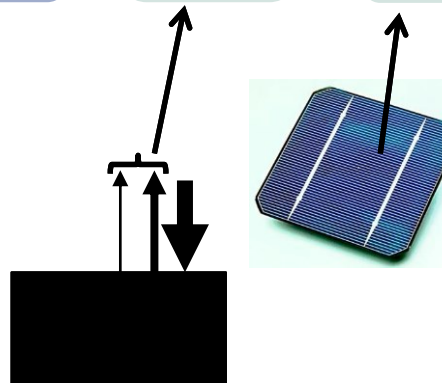


**Thermalization  
loss**

**Sub band gap  
abs. loss**

**Reflection**

**Area loss /  
shadowing**



# Imperfect light absorption

## Lambert-Beer law

intensity in a medium:

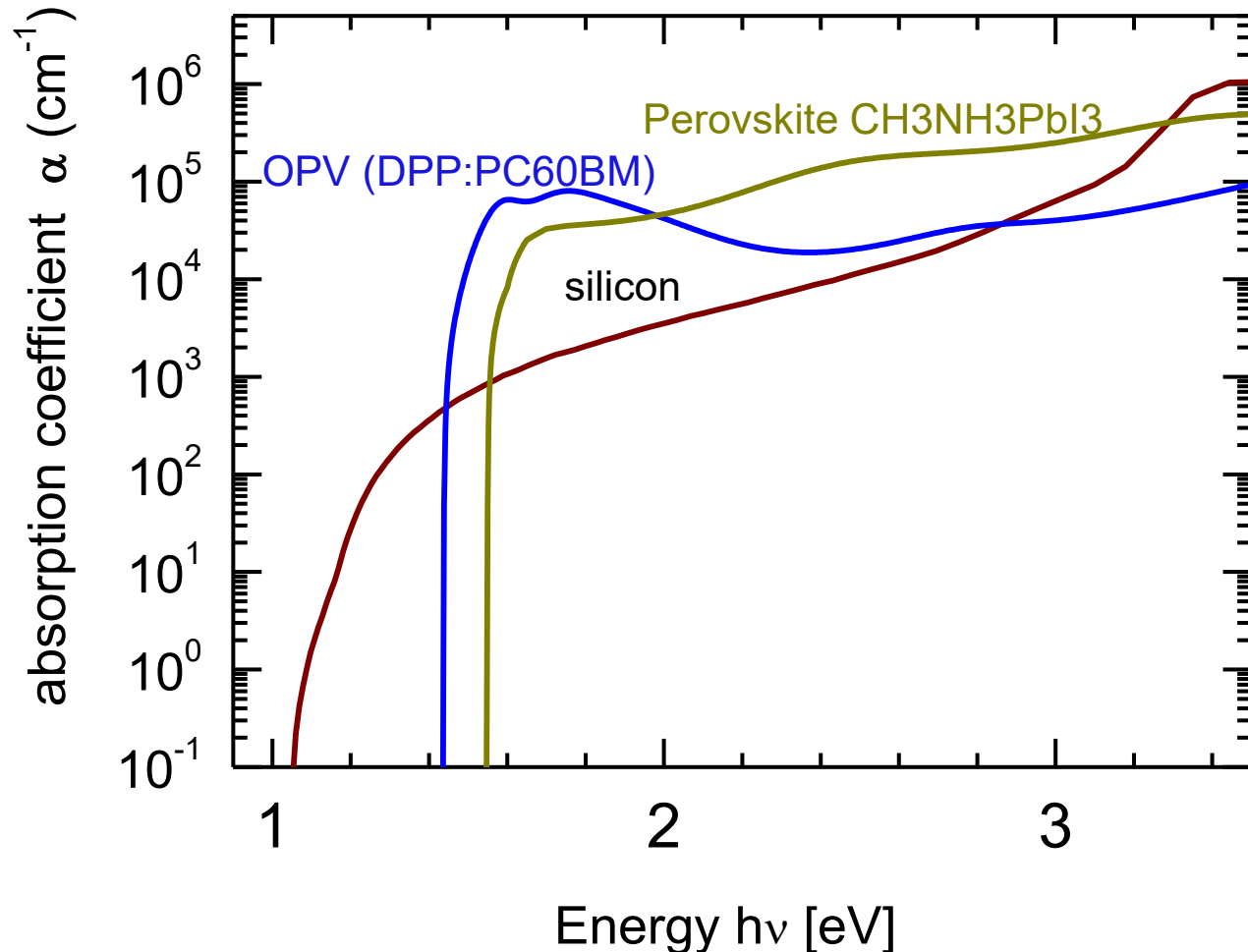
$$I(x) = I_0 e^{-\alpha x}$$

$\alpha$  : absorption coefficient

Absorption of a single pass

$$A(E) = 1 - e^{-\alpha(E)d}$$

$d$  : thickness of the solar cell



# Imperfect light absorption

## Lambert-Beer law

intensity in a medium:

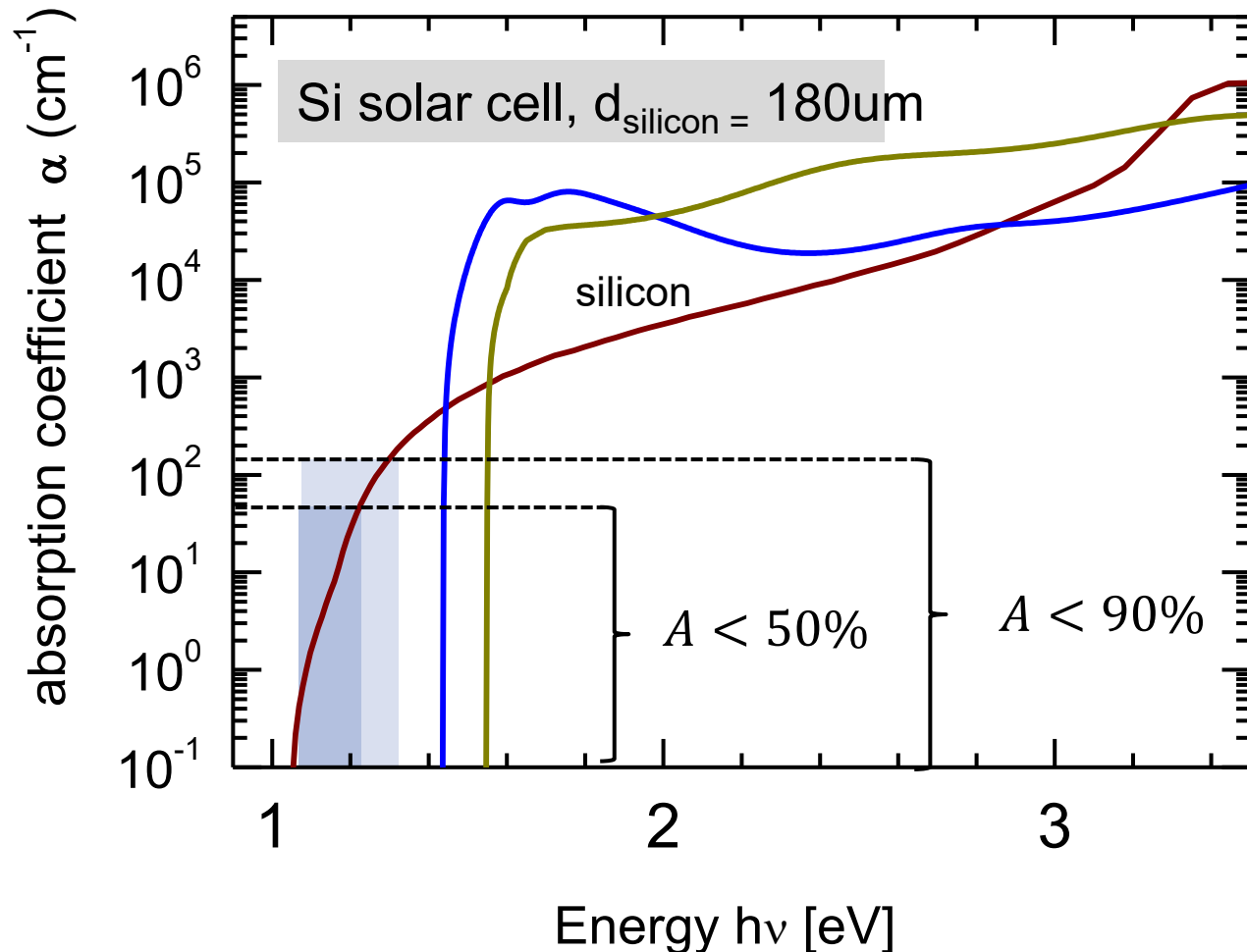
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# Imperfect light absorption

## Lambert-Beer law

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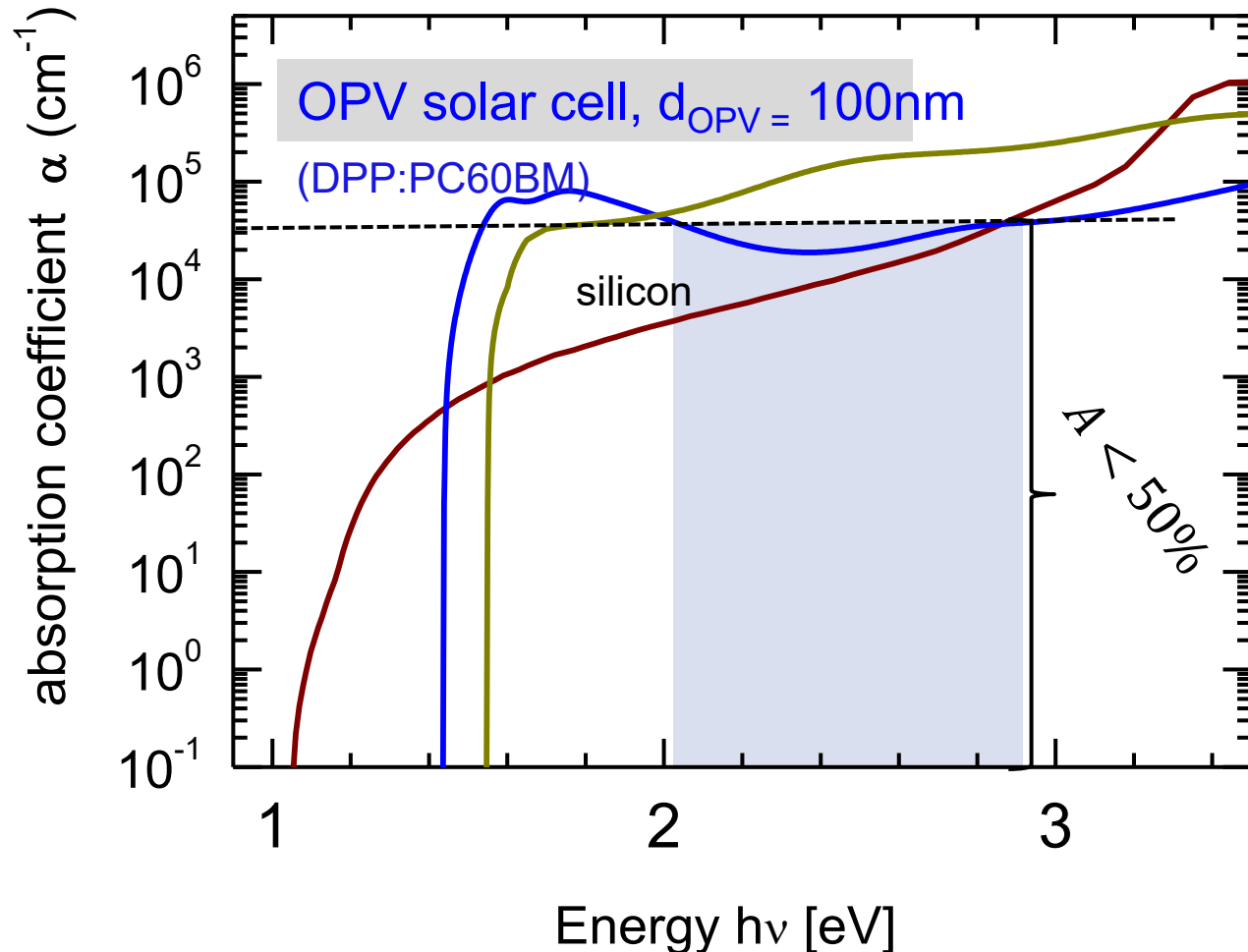
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# Imperfect light absorption

## Lambert-Beer law

intensity in a medium:

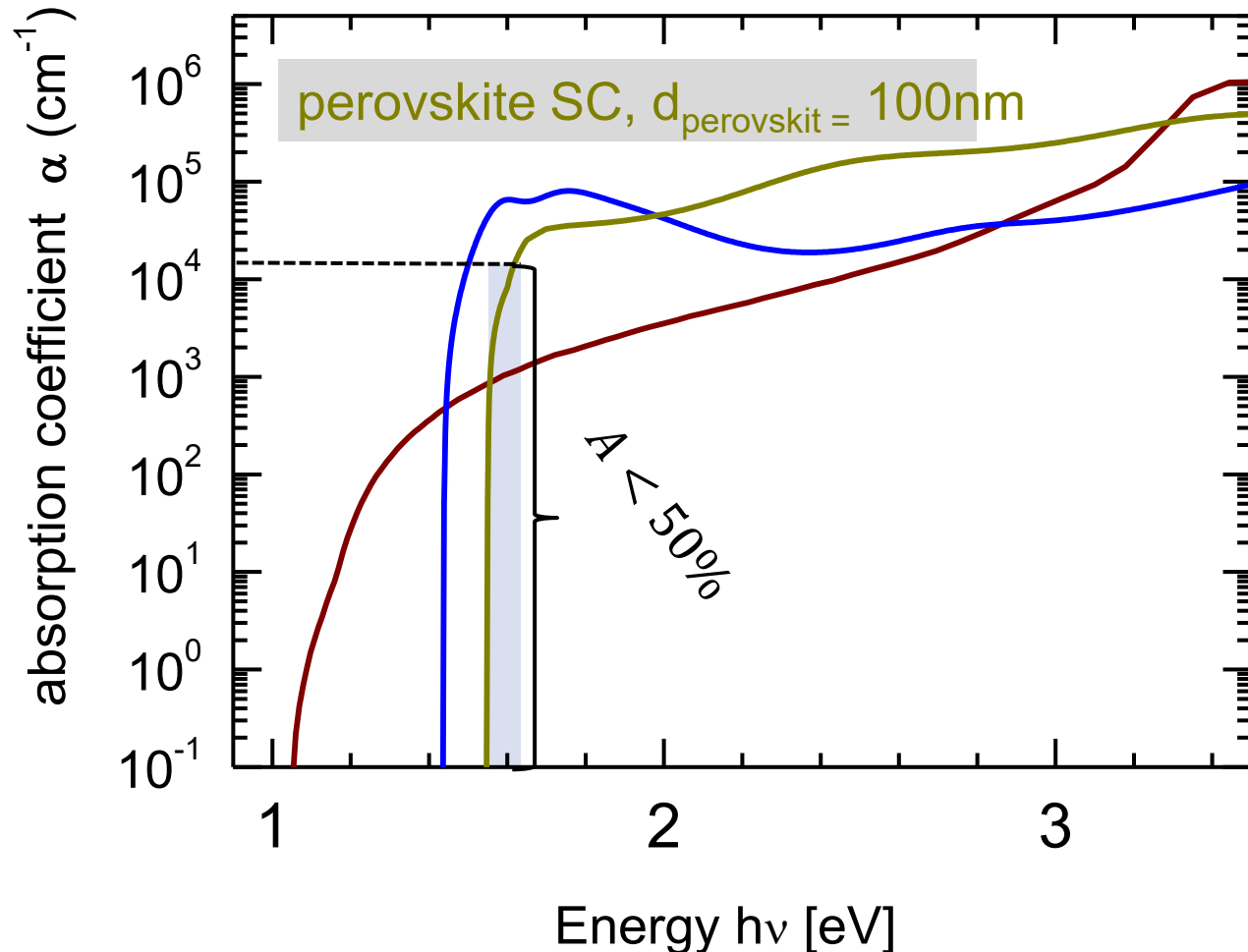
$$I(x) = I_0 e^{-\alpha x}$$

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Absorption of a single pass

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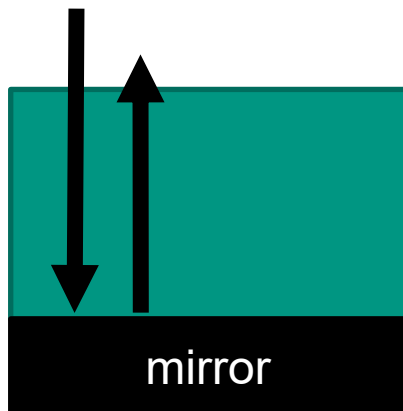
$d$  : thickness of the solar cell



# Imperfect light absorption

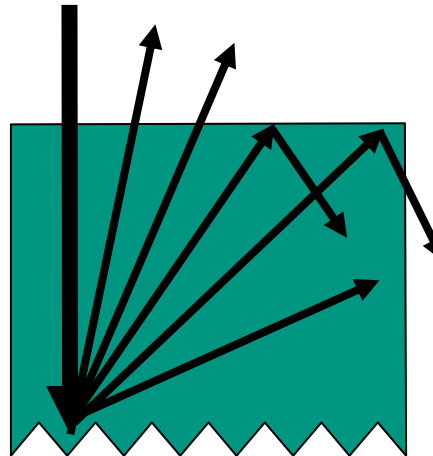
Strategies to improve light absorption are called “LIGHT TRAPPING”

## 1. Back Reflector



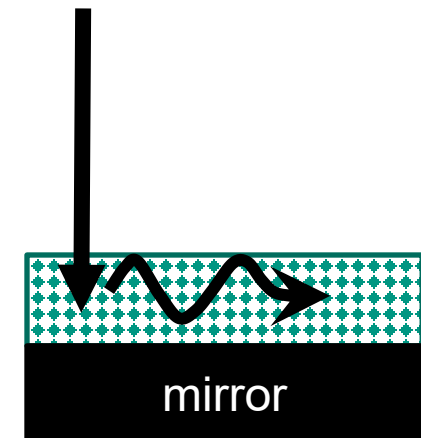
- double the light path

## 2. Light scattering



- increase light path by scattering angle
- total internal reflection for  $\alpha_{\text{sca}} > \alpha_{\text{critica}}$ ,  $\alpha_{\text{critica}} = \text{asin}(n_1/n_2)$

## 2. Light guiding



- Coupling to waveguide modes (requires thin absorbers)
- Coupling via diffraction or nanophotonics

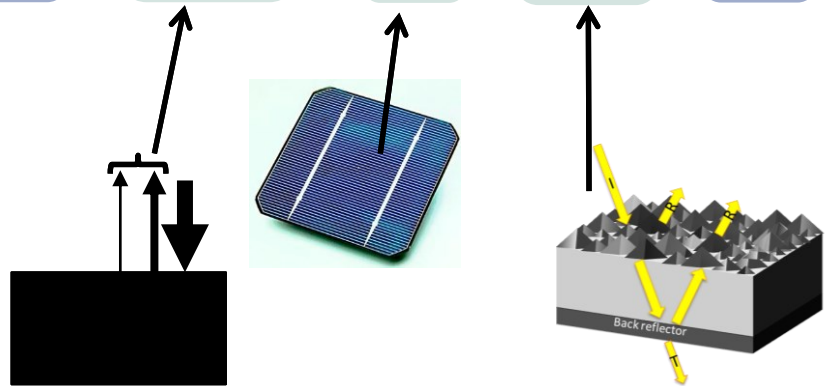
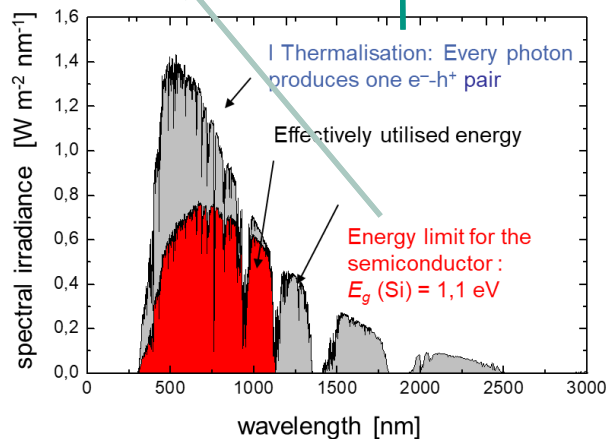
# Solar Cell Efficiency

If we discriminate the optical aspects in the device we get:

Photons

Charge carrier  
dynamics

$$\eta = \frac{\int_0^{E_G} \frac{hc}{\lambda} \Phi_{ph,\lambda} d\lambda}{\int_0^{\infty} \frac{hc}{\lambda} \Phi_{ph,\lambda} d\lambda} \times \frac{E_G \int_0^{E_G} \Phi_{ph,\lambda} d\lambda}{\int_0^{E_G} \frac{hc}{\lambda} \Phi_{ph,\lambda} d\lambda} \times IQE_{el} \times (1 - R) \times \frac{A_f}{A_{tot}} \times IQE_{opt} \times \frac{eV_{oc}}{E_G} \times FF$$



**Thermalization  
loss**

**Sub band gap  
abs. loss**

**Imperf.  
collection**

**Reflection**

**Area loss /  
shadowing**

**Imperfect  
abs**

**Voc  
loss**

**FF  
loss**

# Solar Cell Efficiency

If we discriminate the optical aspects in the device we get:

$$\eta = \underbrace{\frac{\int_0^{\lambda_g} P(\lambda) d\lambda}{\int_0^{\infty} P(\lambda) d\lambda}}_{\text{Photons}} \times \underbrace{\frac{E_g \int_0^{\lambda_g} N(\lambda) d\lambda}{\int_0^{\lambda_g} P(\lambda) d\lambda}}_{\text{Photons}} \times \underbrace{\eta_{col}}_{\text{Charge carrier dynamics}} \times (1 - R) \times \underbrace{\left(\frac{S_{act}}{S_{tot}}\right)}_{\text{Charge carrier dynamics}} \times \underbrace{\eta_{\alpha}}_{\text{Charge carrier dynamics}} \times \underbrace{\frac{qV_{oc}}{E_g}}_{\text{Charge carrier dynamics}} \times \underbrace{FF}_{\text{Charge carrier dynamics}}$$

**NOTE AGAIN! Light management influences the current generation but also the charge carrier dynamics!**

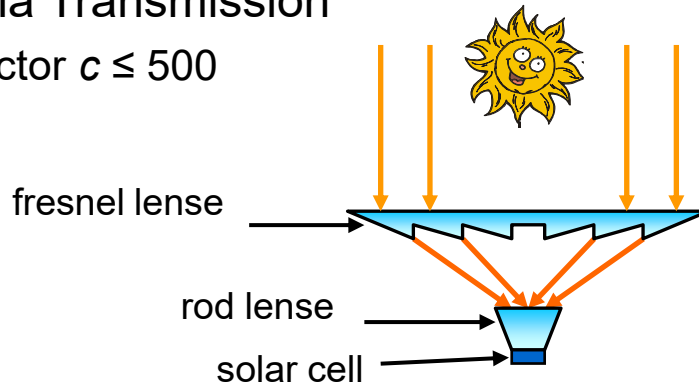
Open circuit voltage

$$V_{oc} = \frac{k_B T}{q} \cdot \ln \left( \frac{J_{SC}}{J_0} + 1 \right)$$

# Concentration Photovoltaics

## Example for impact of light management on Voc!

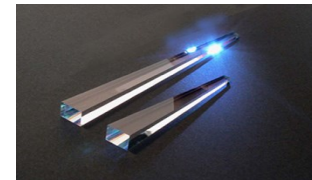
- Concentration via Transmission  
concentration factor  $c \leq 500$



Fresnel lense

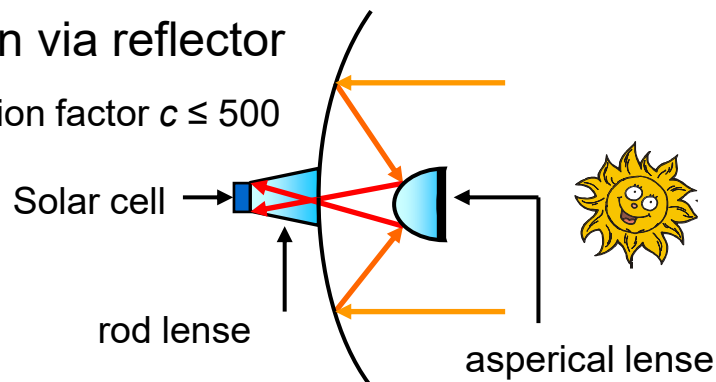


Rod lense

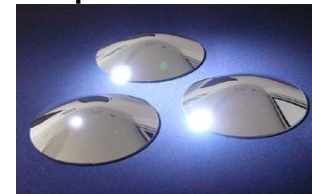


- Concentration via reflector

- concentration factor  $c \leq 500$



asperical lense



# Concentration Photovoltaics

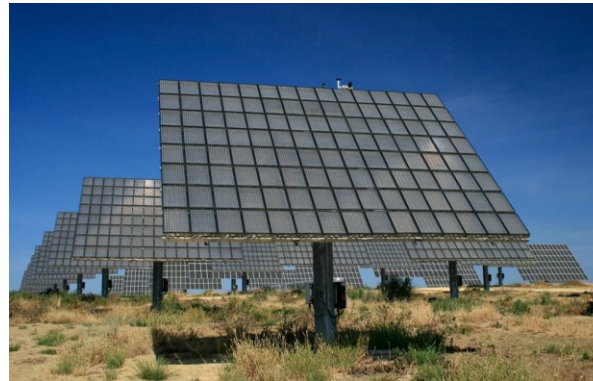
## Example for impact of light management on Voc!

- Concentration via transmission



*SolFocus Inc.*

- Concentration via reflector



*Concentrix Solar GmbH*



# Concentration Photovoltaics

## Example for impact of light management on Voc!

Concentration factor  $c$ : Multiple of the incident intensity of the sun ( $p_{sun} = 1000\text{W/m}^2$ )

$$\Rightarrow j_{SC}^c = c j_{SC}^0 \quad \text{concentrated short circuit current density increases with } c$$

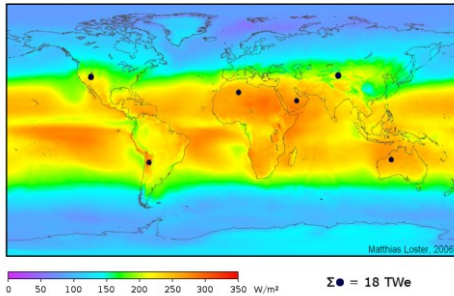
$$\Rightarrow V_{OC}^c \approx \frac{n_{id} kT}{q} \ln \left( \frac{c j_{SC}^0}{j_0} \right) = V_{OC}^0 + \frac{n_{id} kT}{q} \ln c = V_{OC}^0 + \Delta V_{OC}$$

*concentrated Voc increases.*

$$\Rightarrow \eta^c = \frac{p_{max}}{p_{in}^c} = \frac{j_{SC}^c V_{OC}^c FF^c}{p_{in}^c} = \frac{c j_{SC}^0 V_{OC}^c FF^c}{c p_{in}^0} = \frac{j_{SC}^0 V_{OC}^c FF^c}{p_{in}^0}$$

*increase in efficiency only due to increase in Voc (increase in Jsc cancels out).*





*Human mankind consume 18TW per year (2013), for solar cells with 8% efficiency this is the consumed area!*

# EVALUATION BREAK

The evaluation of the lecture will be performed online. An invitation with the link will follow per mail. *Please contribute and help us to improve the lecture!*

## - Solar Energy

([https://onlineumfrage.kit.edu/evasys/public/online/index/index?online\\_php=&p=EUEFM&\\_ga\\_8K KDCKF6WY=GS1.1.1610446757.1.1.1610446816.0&\\_ga=GA1.1.764319627.1610446757&rl\\_a nonymous\\_id=%22b8160e93-4991-4352-a149-8486066f2bcf%22&rl\\_user\\_id=%22wfkrfy45wb86dgzd5ozcgbn31o%22&rl\\_trait=%7B%7D&ONLI NEID=98090540693974710859462656885556377047270](https://onlineumfrage.kit.edu/evasys/public/online/index/index?online_php=&p=EUEFM&_ga_8K KDCKF6WY=GS1.1.1610446757.1.1.1610446816.0&_ga=GA1.1.764319627.1610446757&rl_a nonymous_id=%22b8160e93-4991-4352-a149-8486066f2bcf%22&rl_user_id=%22wfkrfy45wb86dgzd5ozcgbn31o%22&rl_trait=%7B%7D&ONLI NEID=98090540693974710859462656885556377047270))



# OUTLINE

- Light matters for PV
  - Light & solar cell operation principle
  - Optics losses and their relation to the power conversion efficiency
- **State-of-the-art light management in Si solar cells**
  - Reducing light reflection
  - Light trapping
  - Avoiding shading and area losses
- Nanophotonic light management concepts
  - Nanophotonic light management in thin film Si solar cells
  - Nanophotonic light management in perovskite solar cells

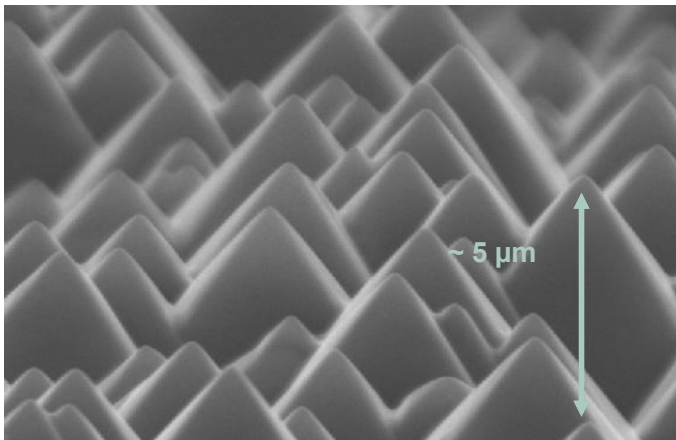
# Reducing light reflection

## *Random pyramid texturing by alkaline etching*

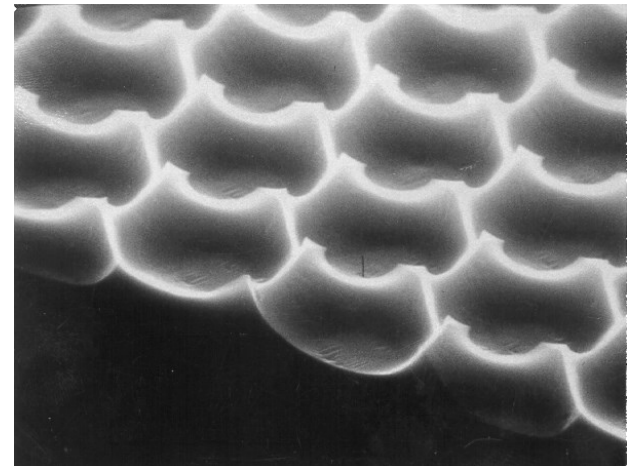
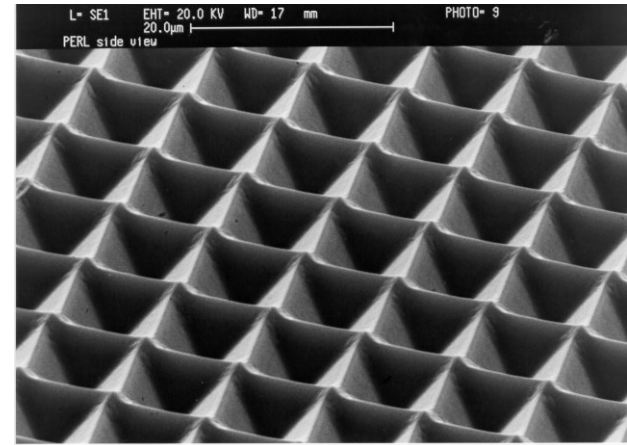


© imec

Etching of Si in KOH or NaOH:  
Etch rate depends on crystallographic planes  
→ formation of pyramids



## *Improved periodic pyramids w. lithography*

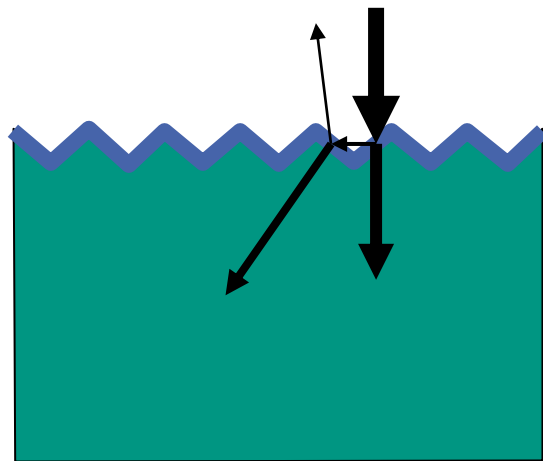


# Reducing light reflection

Additionally, ARCs are deposited on top of the etched pyramids.

$$\begin{aligned} n_{\text{top(glass)}} &= 1.4 \\ n_{\text{Si}} &= 3.5 \end{aligned}$$

$$\text{Optimal RI for an ARC: } n_{\text{ARC}}(\lambda) = \sqrt{n_{\text{Si}}(\lambda)n_{\text{top}}(\lambda)} = 2.2$$

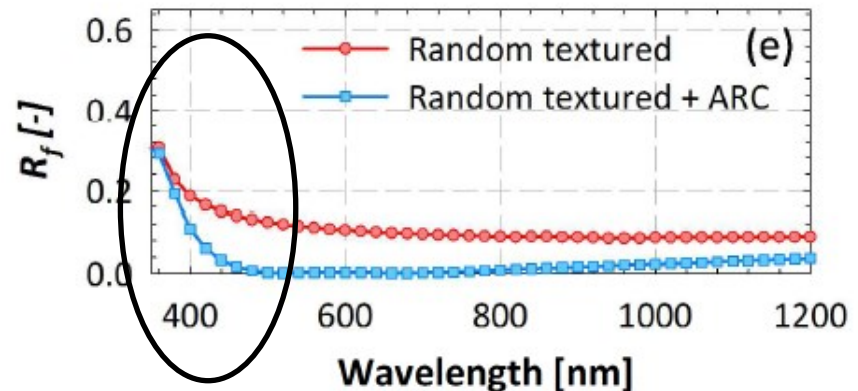


Commonly used (for mono Si):

Pyramid texturing

80nm SiN ARC

[ R(600nm) ~ 0 ]



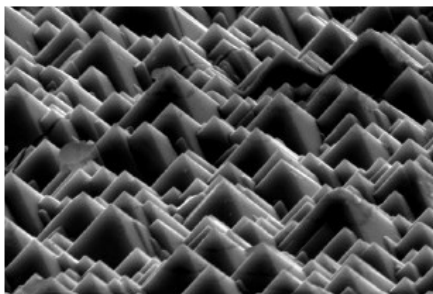
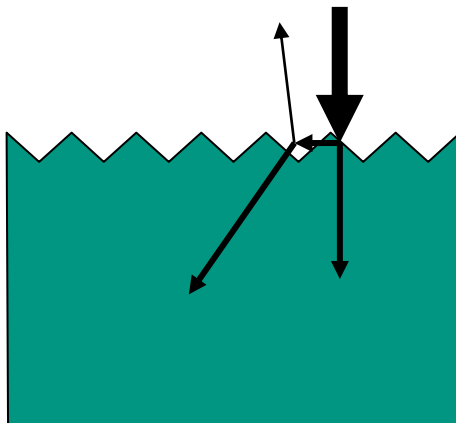
Blue  
!



# Light trapping

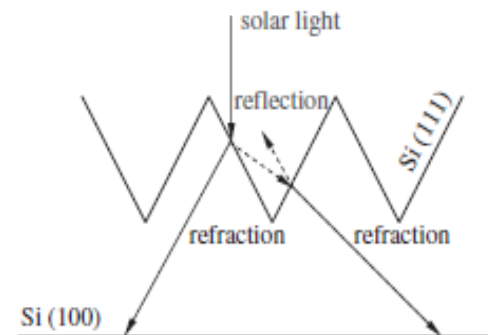
The textured front surface of So solar cells also scatter incident light

-> increase optical path



Textured surface:

- *Multiple reflections*: more impacts, more harvested photons
- *Refraction*: Longer path of the photons in the absorbing medium



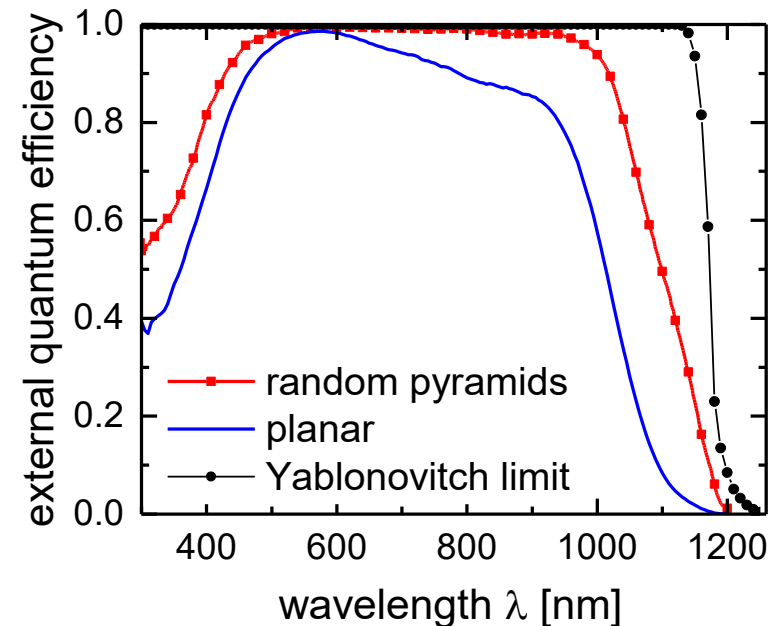
*T. Yagi et al. / Solar Energy Materials & Solar Cells 90 (2006) 2647–2656*

# Light management in Si solar cell

*For an exemplary state-of-the-art Si solar cell*

Jsc increase significantly:

**36mA/cm<sup>2</sup>** → **42mA/cm<sup>2</sup>**  
(planar) (pyramids)



**There is a limit – the Yablonovitch limit ?**

Is says: “... The maximum light path enhancement factor is  **$4 n^2 d$** .”

$$\Rightarrow A = 1 - \exp(-\alpha \langle w \rangle) \approx \alpha \langle w \rangle = 4n^2 \alpha d$$

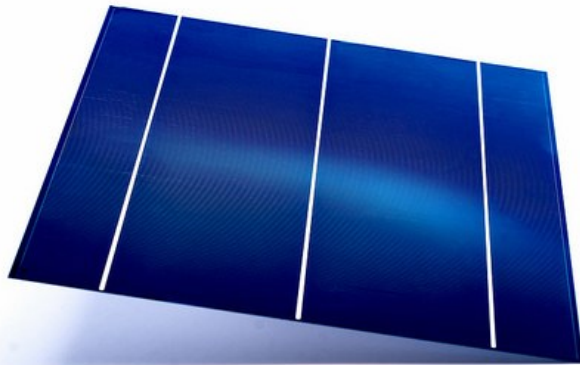
# Avoiding shading and area losses

## Shading losses - the challenge of designing metal contacts

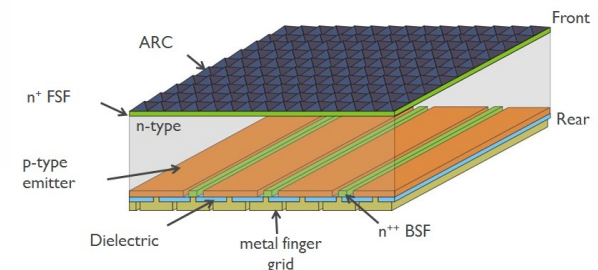
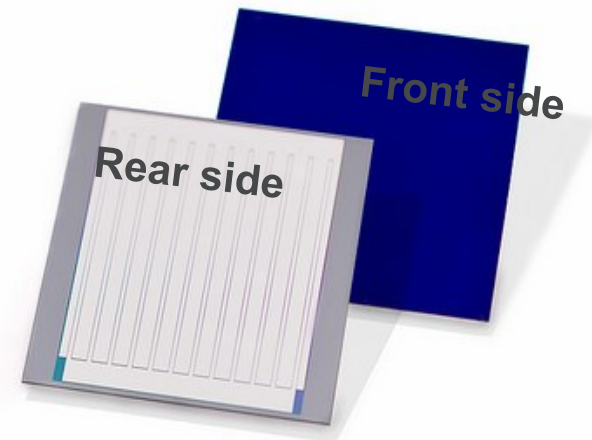
Minimise metallised areas...  
but without losing from series resistance



All contacts on rear-side  
but process becomes very complex



© imec

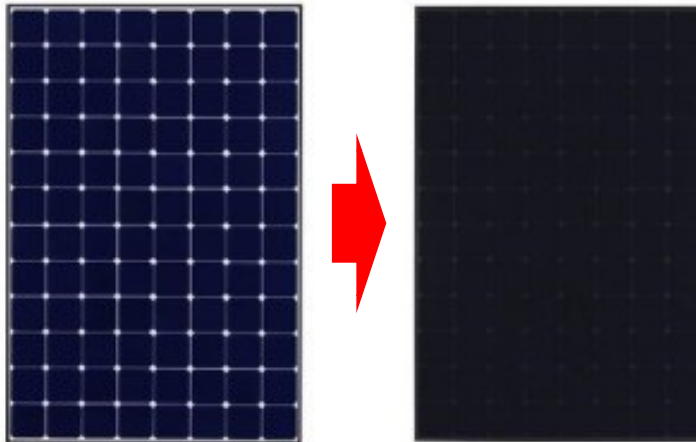




# Avoiding shading and area losses

## Advancing module design

- *Using interdigitated back contact solar cells we obtain black modules*
- *Record power conversion efficiency of such a SI solar 23.8% (Panasonic)*



*This is already close to our goal:*



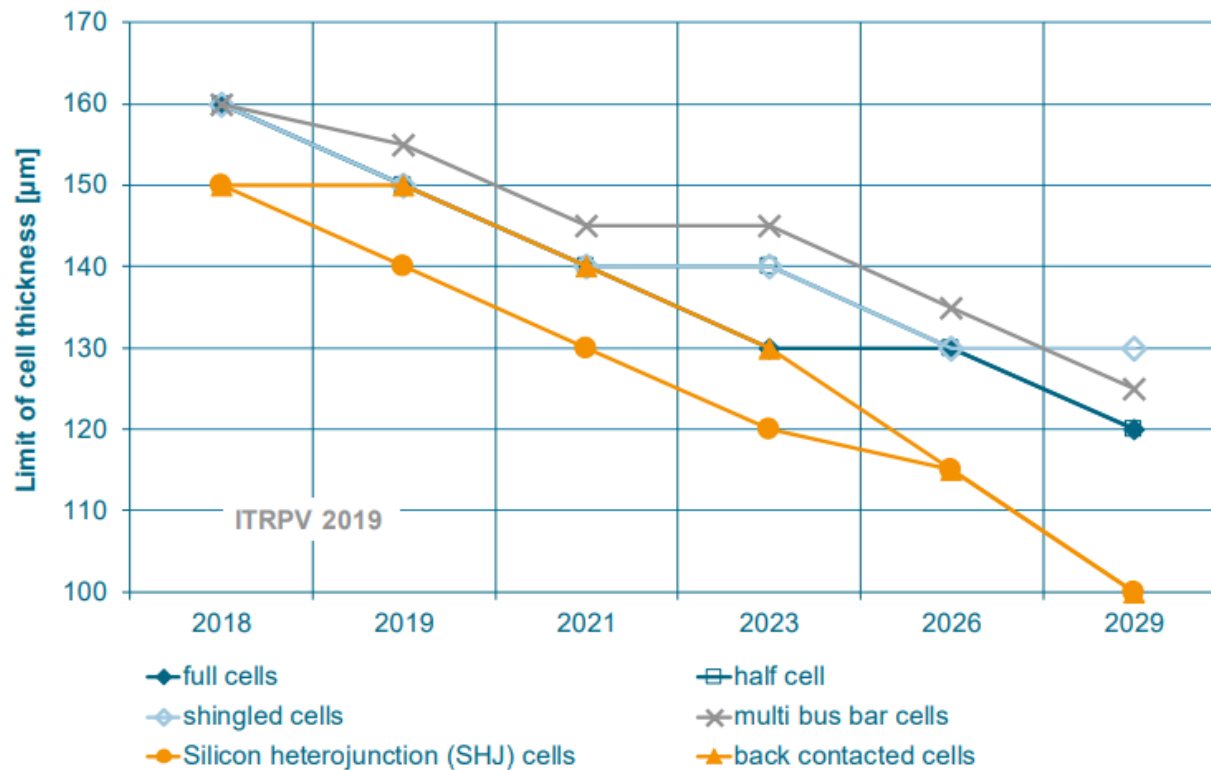
# OUTLINE

- Light matters for PV
  - Light & solar cell operation principle
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- State-of-the-art light management in Si solar cells
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  - Nanophotonic light management in thin film Si solar cells
  - Nanophotonic light management in perovskite solar cells

# Towards thin Si

- Crystalline silicon wafers (c-Si) are an expensive component of the Si solar cell
- Trend of going towards thinner Si wafers (ITRPV)

## Limit of cell thickness in future module technology for different cell types



# But Si is a poor absorber

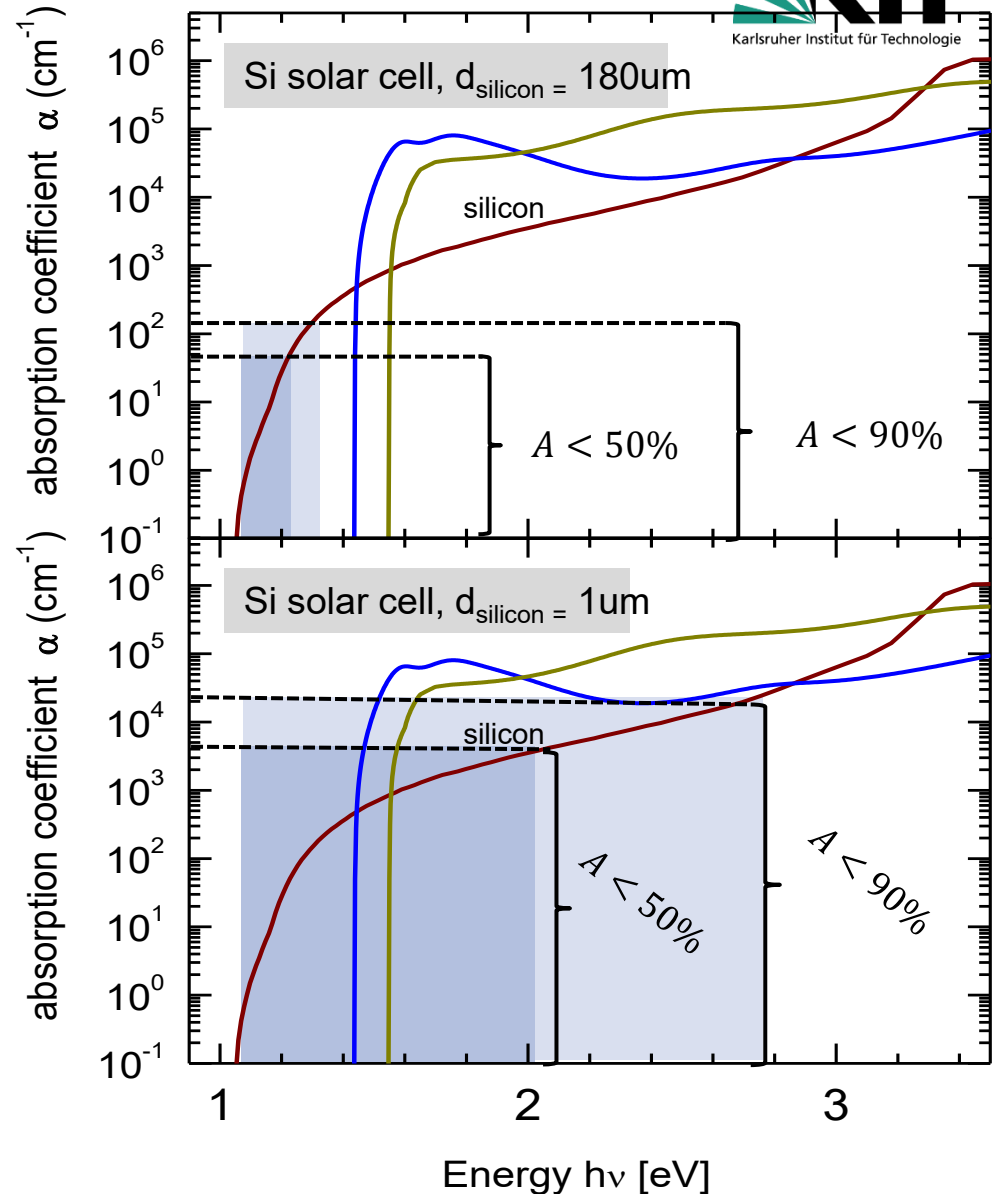
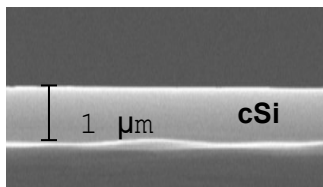
In order to reduce costs one would like to go for thin Si films  $< 50\mu\text{m}$

- Let us look in the future:

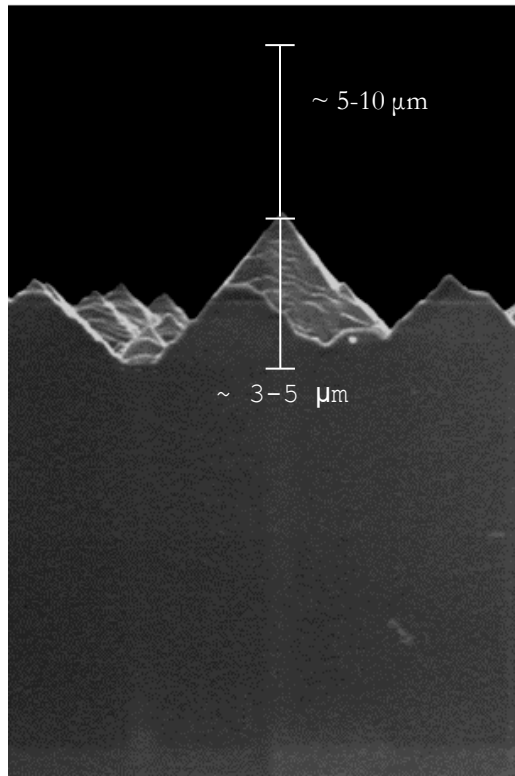
Epifoil ( $\sim 40\mu\text{m}$ )



Epifree ( $\sim 1\mu\text{m}$ )



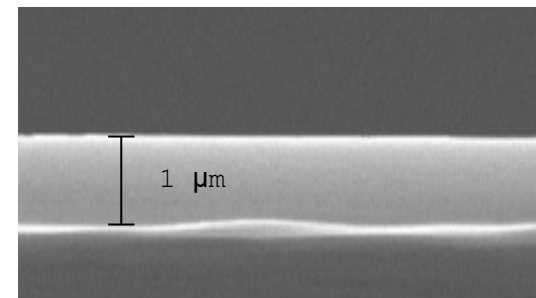
# Conventional light management is not compatible with thin Si



Random pyramid texturing

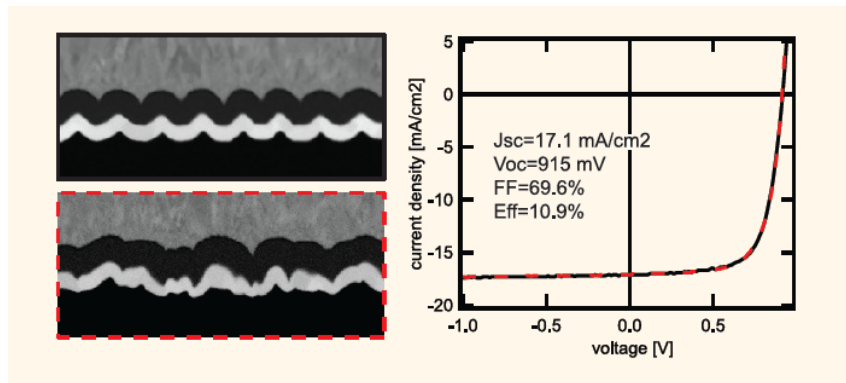
**Advanced light trapping for ultra-thin film technologies is needed!**

**-> NEED TO GO NANO**

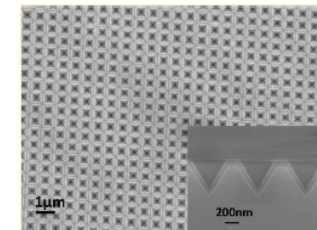


Ultra-thin c-Si films

# Heavy recent research activities on nanoscale light management



Corsin Battaglia et al., *ACS Nano*, 2012, 6 (3), pp. 2790–2797



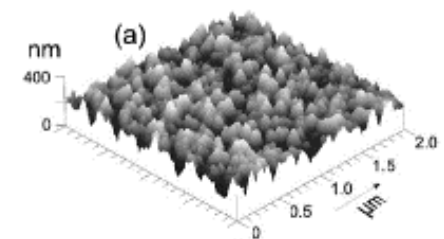
**NANO** LETTERS

Letter

[pubs.acs.org/NanoLett](https://pubs.acs.org/NanoLett)

## Efficient Light Trapping in Inverted Nanopyramid Thin Crystalline Silicon Membranes for Solar Cell Applications

Anastassios Mavrokefalos, Sang Eon Han, Selcuk Yerci, Matthew S. Branham, and Gang Chen\*

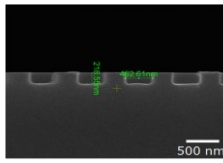
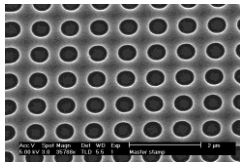


## Black nonreflecting silicon surfaces for solar cells

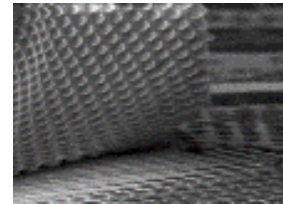
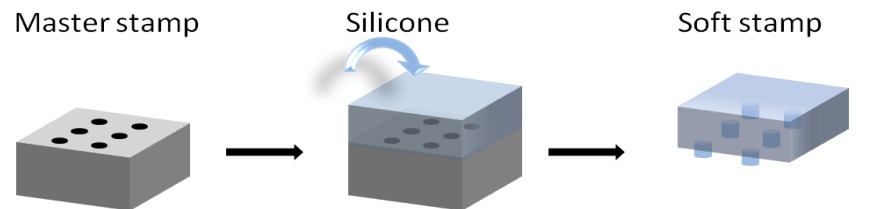
Svetoslav Koynov,<sup>a)</sup> Martin S. Brandt, and Martin Stutzmann  
Walter Schottky Institut, Technische Universität München, 85748 Garching, Germany

# Fabrication of NanoTextures

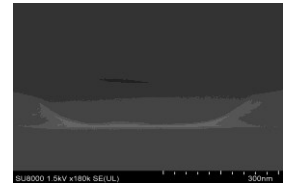
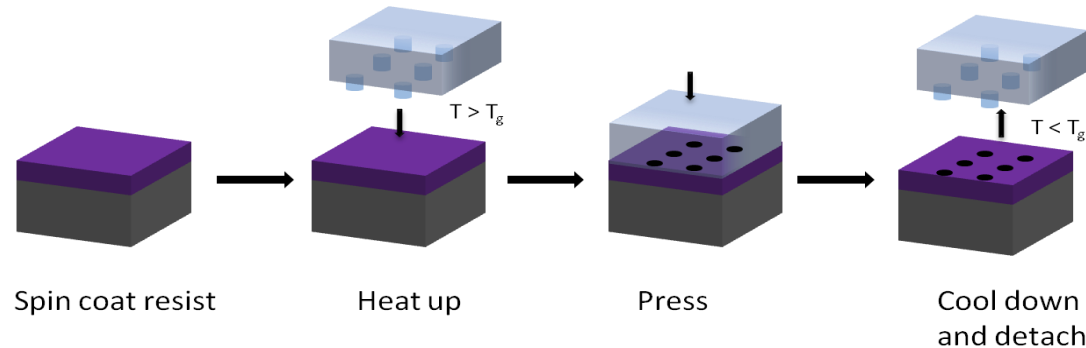
## Nanoimprint lithography (NIL)



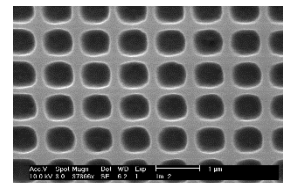
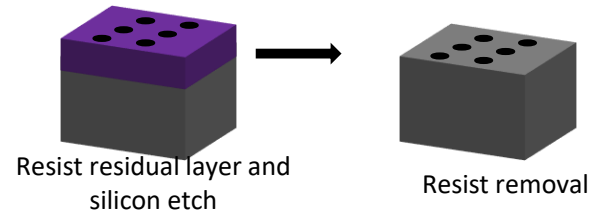
### 1. Soft stamp fabrication



### 2. Nanoimprint



### 3. Pattern transfer

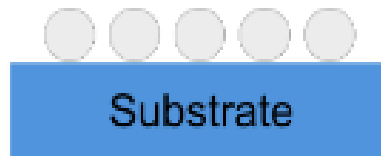




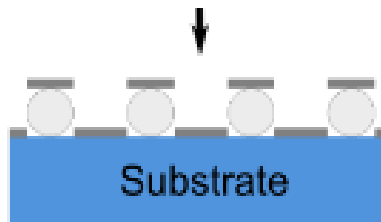
# Fabrication of NanoTextures

## Hole mask colloidal lithography (HCL)

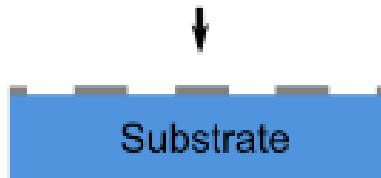
1. Adsorption of PS beads



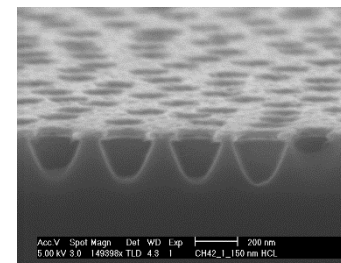
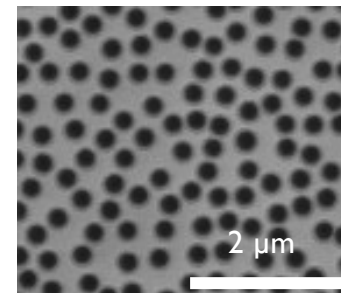
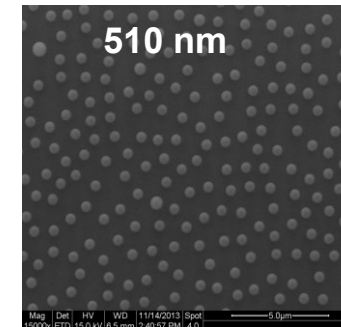
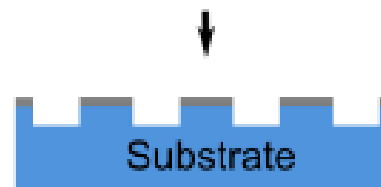
2. Etch mask deposition



3. PS bead removal

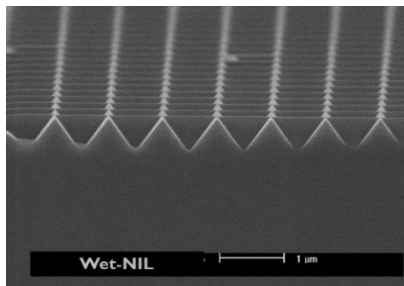


4. Pattern transfer

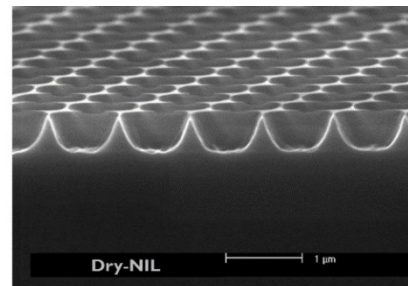


# Fabrication of NanoTextures

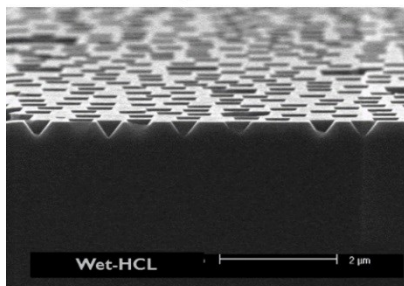
Large variety of nanostructures successfully transferred into Si.



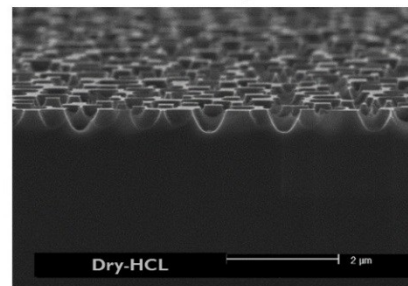
a)



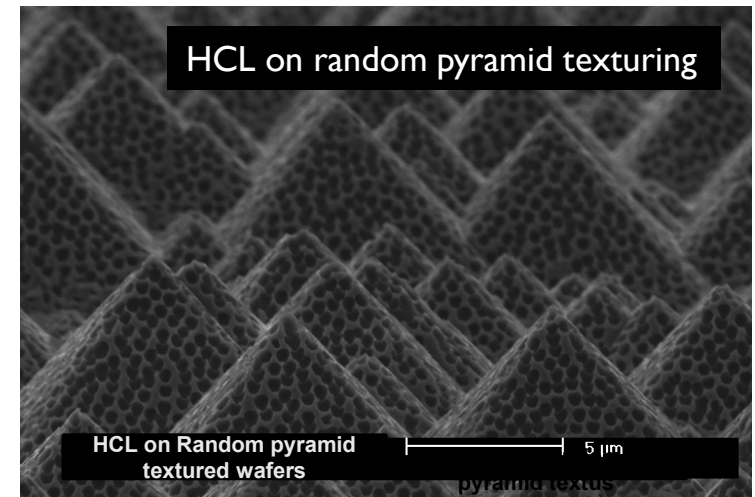
b)



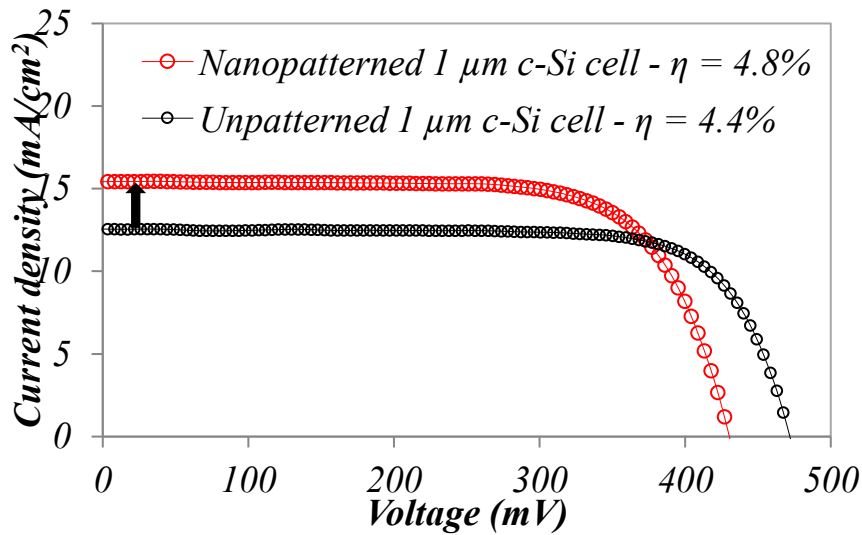
c)



d)

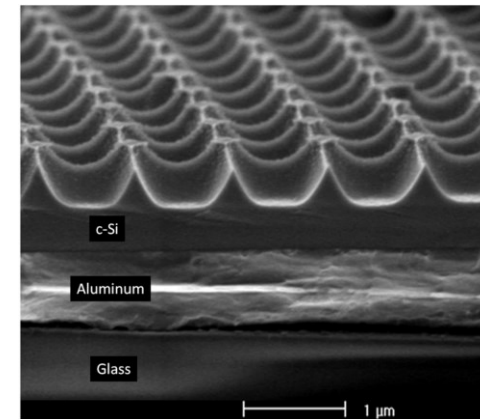


# Solar cell integration: 1 $\mu\text{m}$ epifree



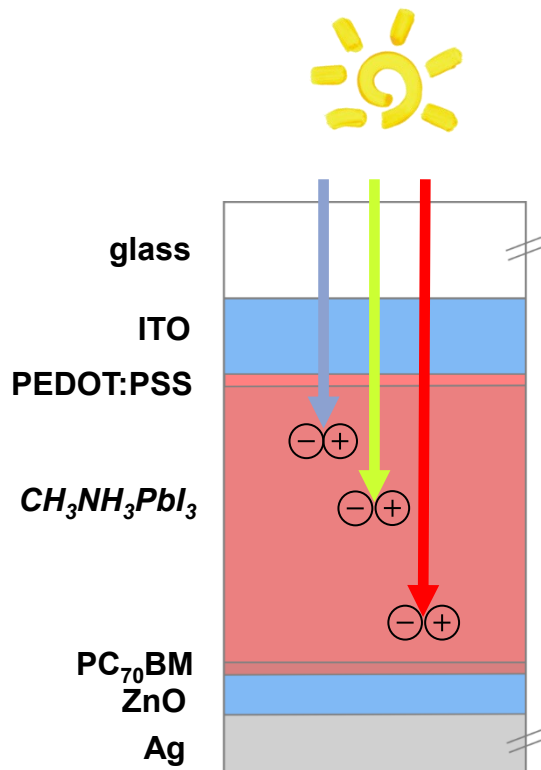
Texturing	$J_{sc}$ [mA/cm <sup>2</sup> ]	$V_{oc}$ [mV]	FF [%]	$\eta$ [%]
Flat	12.5	471	75	4.4
Nanopatterned	15.5	434	72	4.8

C. Trompoukis et al., Appl. Phys. Lett. 101, 103901 (2012)



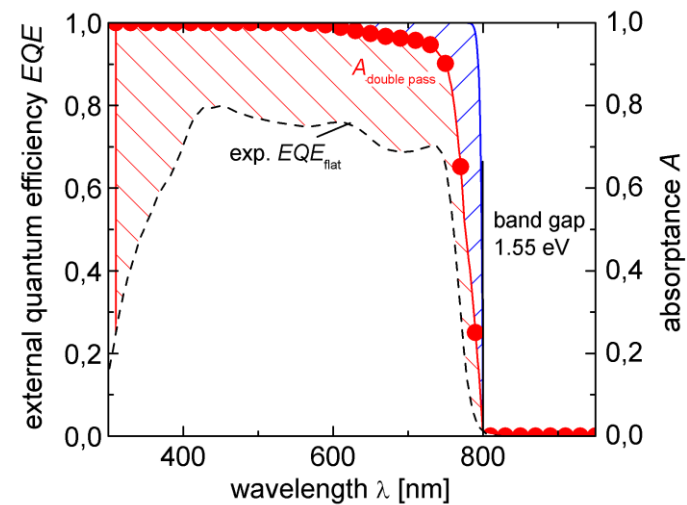
- Increase in current
- $V_{oc}$  decreased due to material degradation from dry etching
- Increased efficiency

# Nanophotonic Light Management in Perovskite Solar Cells



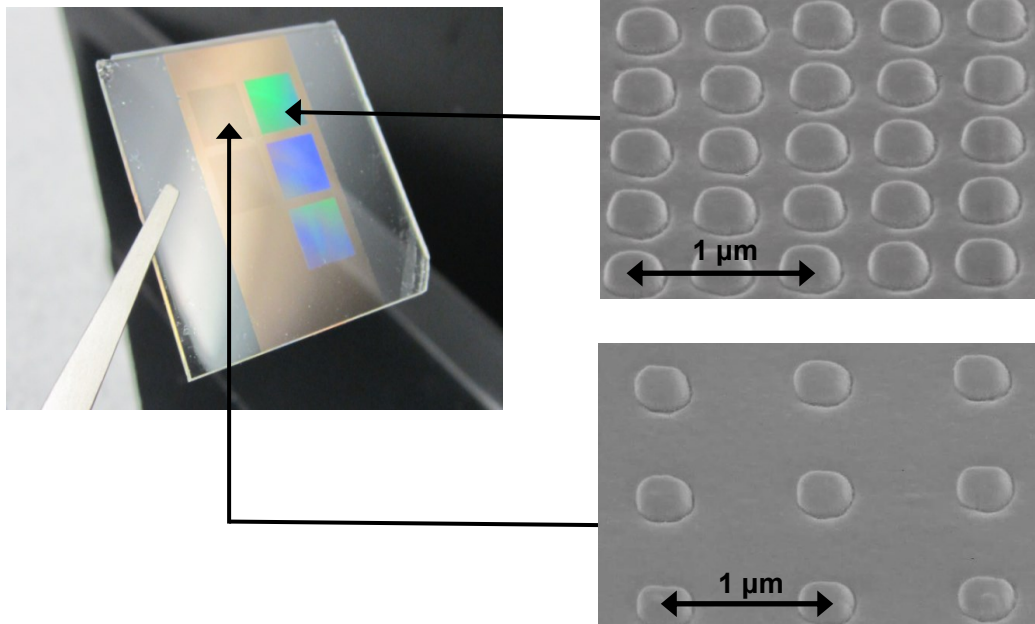
## Perovskite Solar cells:

- Perfect charge carrier collection
- Perfect absorption ( $E > E_g$ )
- Poor light incoupling

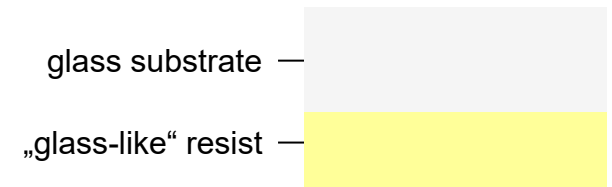


# Nanophotonic electrodes

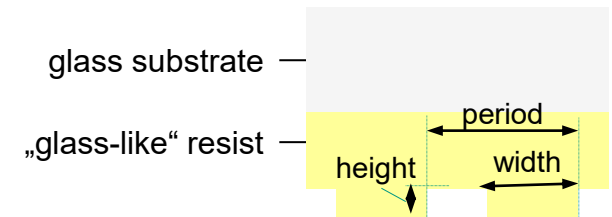
Fabricated by nanoimprint lithography



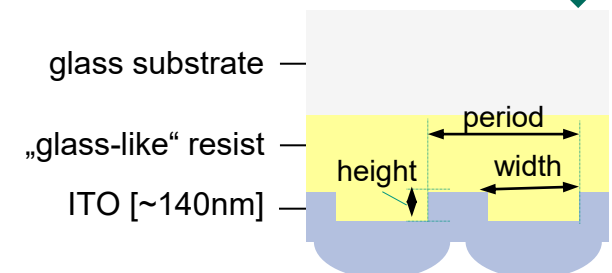
Spin coat resist



Nanoimprint

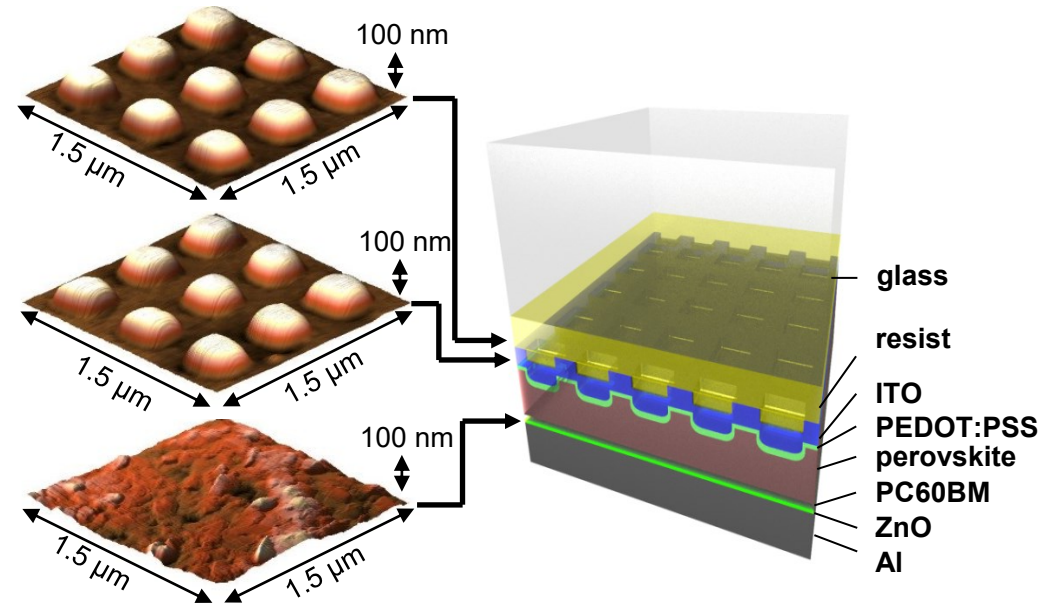
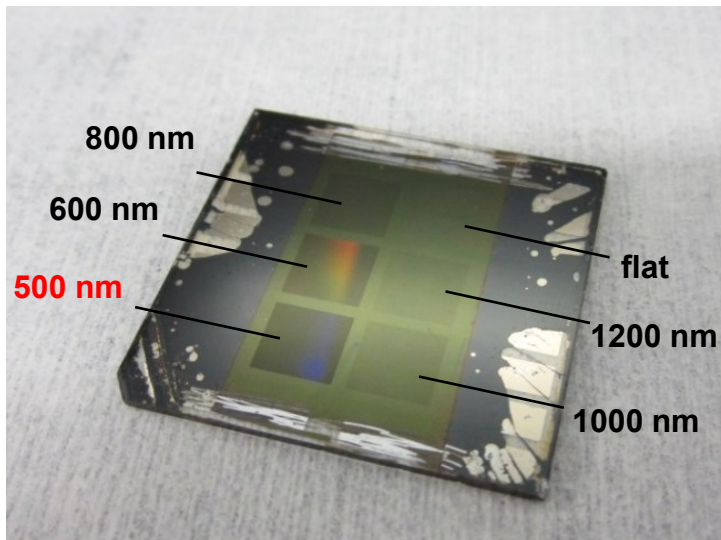


Sputter ITO



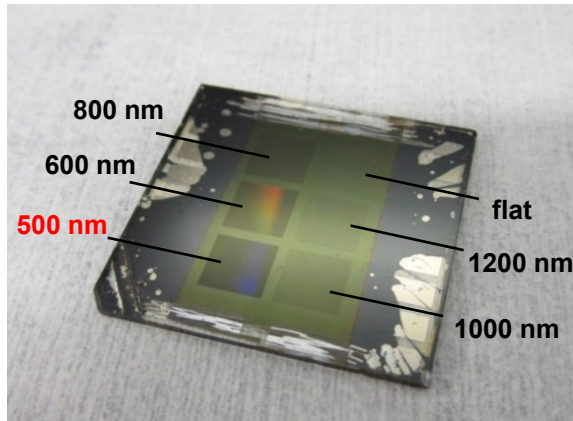
# Nanophotonic electrodes

## Prototype Solar Cells



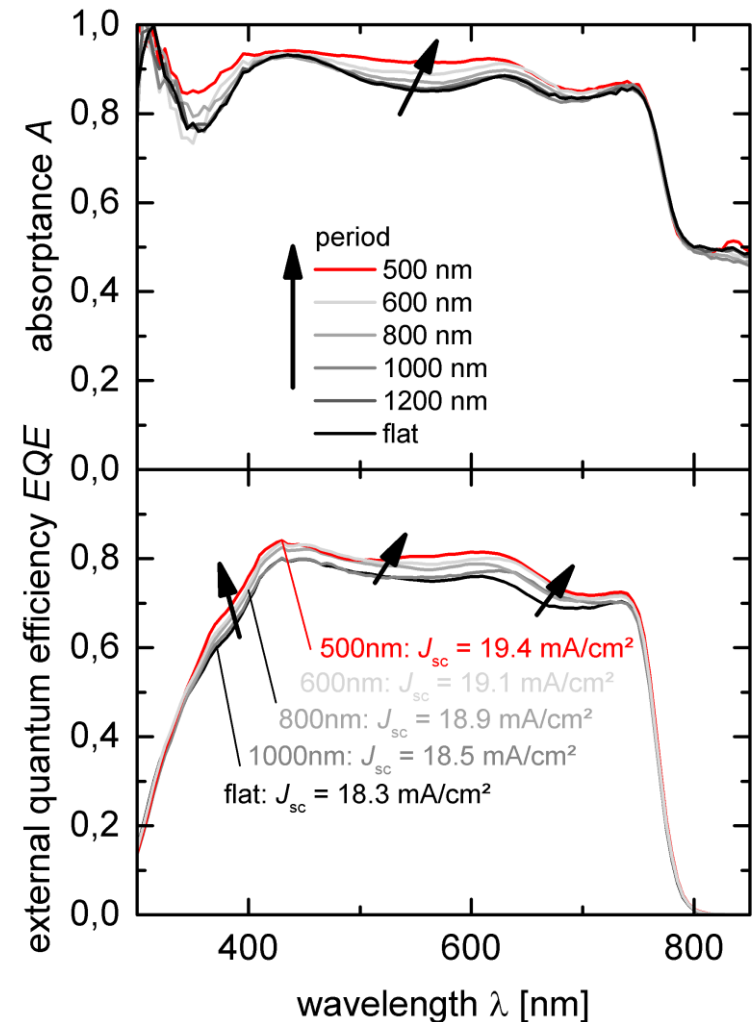
# Nanophotonic electrodes

## Prototype Solar Cells



	FF	$V_{oc}$ [V]	$J_{sc}$ [mA/cm <sup>2</sup> ] (calc. from EQE)	$\eta$ [%]
Flat	0.59	0.89	18.3	9.6
Nanophotonic (period 500 nm)	0.59	0.87	19.4	9.9

- Reduced reflection -> light management
- Still far away from the optimum!





# Take Away Messages

- Light matters for PV !
  - Optics influence directly the  $J_{sc}$ , but indirectly also the  $V_{oc}$  and FF!
  - Key optical losses which require light management are:
    - Reflection
    - Shading
    - Poor absorption => Light trapping
  - State-of-the-art light management in Si solar cells
    - Reducing light reflection => textured front surface + ARC
    - Light trapping => textured front surface
    - Avoiding shading and area losses => IBC solar cells
  - Nanotechnology for next generation light management is in focus of state-of-the-art research
- Examples:
- Nanotextures for thin film cSi solar cells
  - Nanophotonic electrodes for improved light incoupling in perovskite solar cells



# Quick Test

- Discriminate the optical aspects that influence the power conversion efficiency of a solar cell.
- How does light management / optics of a solar cell correlate with (1) short-circuits current density, (2) open-circuit voltage, (3) fill factor?
- Why does the open-circuit voltage of a concentrated solar cell increase with the concentration coefficient? (Derive the correlation!)
- Explain state-of-the-art light management in Si solar cells with regard to (1) light incoupling, (2) light trapping, and (3) reducing inactive areas.
- How does nanophotonic light management differ from conventional light management?